

AFE539F1-Q1 車載用、定電力放電向け 10 ビット・スマート・アナログ・フロント・エンド、PWM 出力付き

1 特長

- 車載アプリケーション用に AEC-Q100 認定済み:
 - 温度グレード 1: $-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$, T_A
- 定電力散逸制御ステート・マシン
 - 10 ビット A/D コンバータ (ADC) 入力
 - デューティ・サイクル 7 ビットのパルス幅変調 (PWM) 出力
 - 不揮発性メモリ (NVM) からのスタンダアロン動作
- I²C/SPI を自動検出
 - V_{IH} : 1.62V ($V_{DD} = 5.5\text{V}$ の場合)
- VREF/MODE ピンにより、プログラミング・モードとスタンダアロン・モードのどちらかを選択
- ユーザーがプログラム可能な NVM
- 内部、外部、VDD の基準電圧
- 幅広い動作範囲
 - 電源: 1.8V ~ 5.5V
- 超小型パッケージ: 16 ピン WQFN (3mm × 3mm)

2 アプリケーション

- 車載用 DC リンク・コンデンサ放電回路
- エレベータ主制御パネル

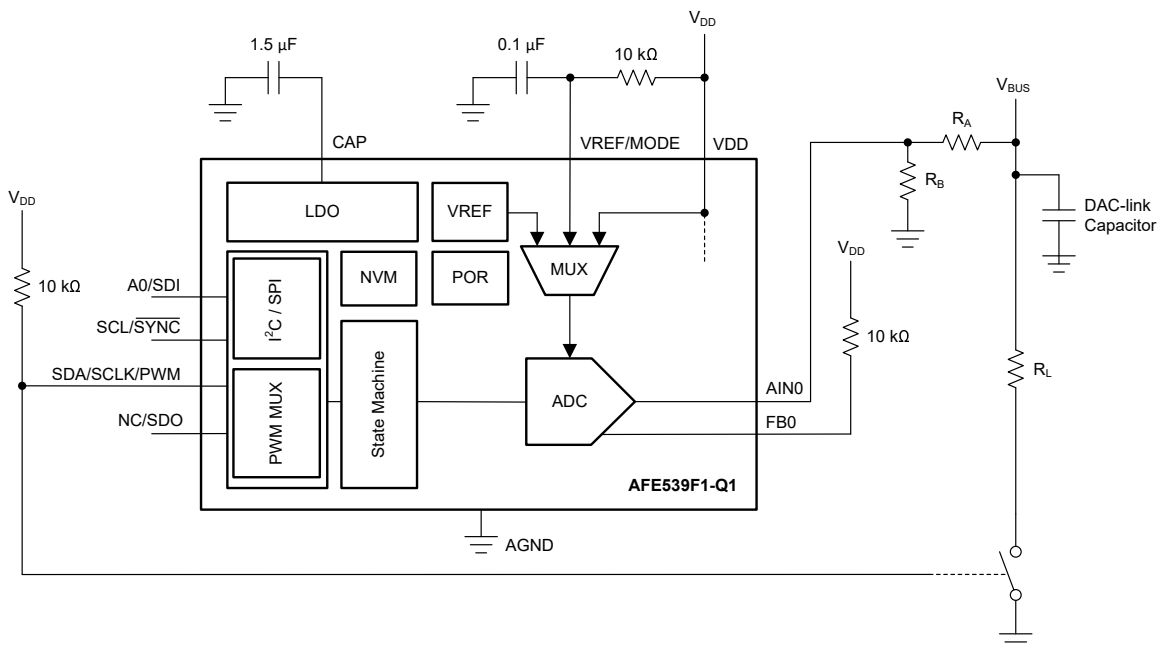
3 概要

AFE539F1-Q1 は、定電力散逸制御を目的とした 10 ビットのスマート・アナログ・フロント・エンド (AFE) です。AFE539F1-Q1 は、抵抗性負荷において定電力散逸を必要とするあらゆる場所で、印加電圧にかかわらず独立に使用できます。AFE539F1-Q1 は、ADC 入力と PWM 出力を備えています。このデバイスは、定電力散逸コントローラとしてあらかじめプログラムされたステート・マシンを内蔵しています。AFE539F1-Q1 は、車載用 DC リンク・コンデンサ放電回路や、一般的な定電力加熱アプリケーション向けの優れた選択肢になります。AFE539F1-Q1 は、NVM にプログラムされたパラメータとは独立して動作するため、このスマート AFE をプロセッサレス・アプリケーションや設計の再利用に使用できます。また、このデバイスは、I²C と SPI の自動検出、および内部基準電圧を備えています。

パッケージ情報

| 部品番号 | パッケージ ⁽¹⁾ | パッケージ・サイズ ⁽²⁾ |
|-------------|----------------------|--------------------------|
| AFE539F1-Q1 | RTE (WQFN, 16) | 3mm × 3mm |

- 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。
- パッケージ・サイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。



AFE539F1-Q1 を使用した定電力放電回路



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4 Revision History

| DATE | REVISION | NOTES |
|-----------|----------|-----------------|
| July 2023 | * | Initial release |

5 Pin Configuration and Functions

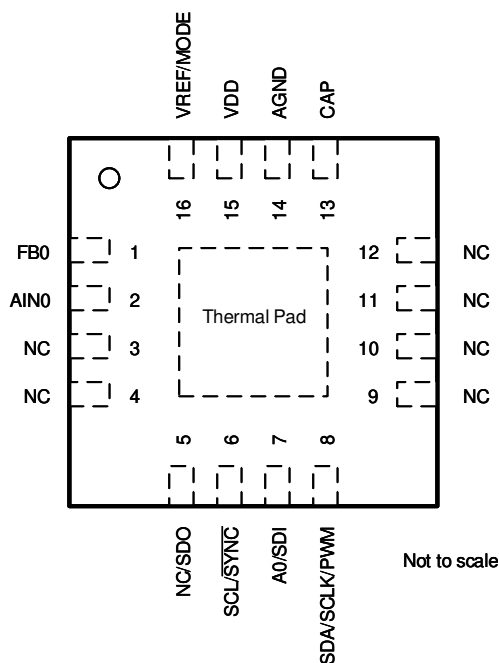


図 5-1. RTE Package, 16-pin WQFN (Top View)

表 5-1. Pin Functions

| PIN | | TYPE | DESCRIPTION |
|-----|------------------|------------------|---|
| NO. | NAME | | |
| 1 | FB0 | Input | Connect this pin to VDD with a pullup resistor. |
| 2 | AIN0 | Input | Analog input for ADC0. |
| 3 | NC | — | Not connected. |
| 4 | NC | — | Not connected. |
| 5 | NC/SDO | Input/ Output | This pin is configurable as SDO. For SDO function, connect this pin to the IO voltage with an external pullup resistor. Leave this pin unconnected if not configured as SDO. |
| 6 | SCL/SYNC | Output | I ² C serial interface clock or SPI chip select input. Connect this pin to the IO voltage using an external pullup resistor. |
| 7 | A0/SDI | Input | Address configuration input for I ² C or serial data input for SPI. In A0 function, connect this pin to VDD, AGND, SDA, or SCL for address configuration. In SDI function, this pin does not need to be pulled up or pulled down. |
| 8 | SDA/ SCLK/PWM | Input/ Output | Bidirectional I ² C serial data bus or SPI clock input. Connect this pin to the IO voltage using an external pullup resistor. This pin acts as the PWM output for constant power-dissipation control. Pull the VREF/ MODE pin high to enable PWM output. |
| 9 | NC | — | Not connected. |
| 10 | NC | — | Not connected. |
| 11 | NC | — | Not connected. |
| 12 | NC | — | Not connected. |
| 13 | CAP | Power | External bypass capacitor for the internal LDO. Connect a capacitor (approximately 1.5 μ F) between CAP and AGND. |
| 14 | AGND | Ground | Ground reference point for all circuitry on the device. |
| 15 | VDD | Power | Supply voltage: 1.8 V to 5.5 V |

表 5-1. Pin Functions (continued)

| PIN | | TYPE | DESCRIPTION |
|-------------|---------------|--------|--|
| NO. | NAME | | |
| 16 | VREF/ MODE | Input | External reference or interface mode select input. Connect a capacitor (approximately 0.1 μ F) between VREF/MODE and AGND. Use a pullup resistor to VDD when the external reference is not used. Make sure that this pin does not ramp up before VDD. In case an external reference is used or when in interface select mode, make sure the reference ramps up after VDD. In interface select mode. Pull this pin low to enable I ² C/SPI communication. Pull this pin high to enable PWM output. |
| Thermal pad | Thermal Pad | Ground | Connect the thermal pad to AGND. |

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | MIN | MAX | UNIT |
|------------------|--|------|-----------------------|------|
| V _{DD} | Supply voltage, V _{DD} to AGND | −0.3 | 6 | V |
| | Digital inputs to AGND | −0.3 | V _{DD} + 0.3 | V |
| | V _{FBX} to AGND | −0.3 | V _{DD} + 0.3 | V |
| | A _{IN0} to AGND | −0.3 | V _{DD} + 0.3 | V |
| V _{REF} | External reference, V _{REF} to AGND | −0.3 | V _{DD} + 0.3 | V |
| | Current into any pin except the AIN0, VDD, and AGND pins | −10 | 10 | mA |
| T _J | Junction temperature | −40 | 150 | °C |
| T _{stg} | Storage temperature | −65 | 150 | °C |

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| V _(ESD) | Electrostatic discharge | Human body model (HBM), per AEC Q100-002 ⁽¹⁾ HBM ESD classification level 2 | ±2000 | V |
| | | Charged device model (CDM), per AEC Q100-011 CDM ESD classification level C4B | ±750 | |
| | | Corner pins (1, 4, 5, 8, 9, 12, 13, and 16) All pins | ±500 | |

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | NOM | MAX | UNIT |
|------------------|---|------|-----|-----------------|------|
| V _{DD} | Positive supply voltage to ground (AGND) | 1.7 | | 5.5 | V |
| V _{REF} | External reference to ground (AGND) | 1.7 | | V _{DD} | V |
| V _{IH} | Digital input high voltage, 1.7 V < V _{DD} ≤ 5.5 V | 1.62 | | | V |
| V _{IL} | Digital input low voltage | | | 0.4 | V |
| C _{CAP} | External capacitor on CAP pin | 0.5 | | 15 | μF |
| T _A | Ambient temperature | −40 | | 125 | °C |

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | | AFE539F1-Q1 | UNIT |
|-------------------------------|--|-------------|------|
| | | RTE (WQFN) | |
| | | 16 PINS | |
| R _{θJA} | Junction-to-ambient thermal resistance | 49 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 50 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 24.1 | °C/W |
| Ψ _{JT} | Junction-to-top characterization parameter | 1.1 | °C/W |
| Ψ _{JB} | Junction-to-board characterization parameter | 24.1 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | 8.7 | °C/W |

- (1) For information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics application report](#).

6.5 Electrical Characteristics: ADC Input

minimum and maximum specifications at $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ and typical specifications at $T_A = 25^{\circ}\text{C}$, $1.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, reference input tied to VDD, gain = 1 ×, and digital inputs at VDD or AGND (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------|--|--|------|-----|----------|------|
| STATIC PERFORMANCE | | | | | | |
| | Resolution | | 10 | | | Bits |
| INL | Integral nonlinearity ^{(1) (2)} | | −2 | | 2 | LSB |
| DNL | Differential nonlinearity ^{(1) (2)} | | −1 | | 1 | LSB |
| | Offset error ^{(1) (2)} | $1.7\text{ V} \leq V_{DD} < 2.7\text{ V}$ | −5 | 0 | 5 | mV |
| | | $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ | −5 | 0 | 5 | |
| | Gain error ^{(1) (2)} | | −1 | | 1 | %FSR |
| INPUT | | | | | | |
| | Input voltage range | External $V_{REF} = V_{DD}$ | 0 | | V_{DD} | V |
| DYNAMIC PERFORMANCE | | | | | | |
| | Data rate ⁽²⁾ | ADC averaging setting is 4 samples | 1406 | | 2008 | SPS |
| | Sampling capacitor | | | 10 | | pF |

(1) For external reference and internal reference $V_{DD} \geq 1.21 \times \text{gain} + 0.2\text{ V}$, between end-point codes: 8d to 1016d.

(2) Specified by design and characterization, not production tested.

6.6 Electrical Characteristics: General

minimum and maximum specifications at $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ and typical specifications at $T_A = 25^{\circ}\text{C}$, $1.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, reference input tied to VDD, gain = 1 × and digital inputs at VDD or AGND (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------|---|---|--------|-------|-----------------|--------|
| INTERNAL REFERENCE | | | | | | |
| | Initial accuracy | T _A = 25°C for all measurements | 1.1979 | 1.212 | 1.224 | V |
| | Reference output temperature coefficient ^{(1) (2)} | | | | 60 | ppm/°C |
| EXTERNAL REFERENCE | | | | | | |
| | External reference input range | | 1.7 | | V _{DD} | V |
| | V _{REF} input impedance ⁽¹⁾ | | | 192 | | kΩ |
| EEPROM | | | | | | |
| | Endurance ⁽¹⁾ | −40°C ≤ T _A ≤ +85°C | | 20000 | | Cycles |
| | | T _A = 125°C | | 1000 | | |
| | Data retention ⁽¹⁾ | | | 50 | | Years |
| | EEPROM programming write cycle time ⁽¹⁾ | | | | 200 | ms |
| | Device boot-up time ⁽¹⁾ | Time taken from power valid (V _{DD} ≥ 1.7 V) to output valid state (output state as programmed in EEPROM), 0.5-μF capacitor on the CAP pin | | 5 | | ms |
| DIGITAL INPUTS | | | | | | |
| | Pin capacitance | Per pin | | 10 | | pF |
| POWER | | | | | | |
| I _{DD} | Current flowing into VDD | Sleep mode, internal reference powered down, external reference at 5.5 V | | | 28 | μA |
| | | Sleep mode, internal reference enabled, additional current through internal reference | | 10 | | |
| | Current flowing into VDD ⁽¹⁾ | ADC channel enabled, internal reference enabled, additional current through internal reference | | | 12.5 | μA-ch |
| | | Normal operation, state-machine enabled | | | 900 | μA |

(1) Specified by design and characterization, not production tested.

(2) Measured at -40°C and $+125^{\circ}\text{C}$ and calculated the slope.

6.7 Timing Requirements: I²C Standard Mode

all input signals are timed from VIL to 70% of $V_{pull-up}$, $1.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$, and $1.7\text{ V} \leq V_{pull-up} \leq V_{DD}$

| | | MIN | NOM | MAX | UNIT |
|-------------|--|------|-----|------|---------------|
| f_{SCLK} | SCL frequency | | | 100 | kHz |
| t_{BUF} | Bus free time between stop and start conditions | 4.7 | | | μs |
| t_{HDSTA} | Hold time after repeated start | 4 | | | μs |
| t_{SUSTA} | Repeated start setup time | 4.7 | | | μs |
| t_{SUSTO} | Stop condition setup time | 4 | | | μs |
| t_{HDDAT} | Data hold time | 0 | | | ns |
| t_{SUDAT} | Data setup time | 250 | | | ns |
| t_{LOW} | SCL clock low period | 4700 | | | ns |
| t_{HIGH} | SCL clock high period | 4000 | | | ns |
| t_F | Clock and data fall time | | | 300 | ns |
| t_R | Clock and data rise time | | | 1000 | ns |
| t_{VDDAT} | Data valid time, $R = 360\ \Omega$, $C_{trace} = 23\text{ pF}$, $C_{probe} = 10\text{ pF}$ | | | 3.45 | μs |
| t_{VDACK} | Data valid acknowledge time, $R = 360\ \Omega$, $C_{trace} = 23\text{ pF}$, $C_{probe} = 10\text{ pF}$ | | | 3.45 | μs |

6.8 Timing Requirements: I²C Fast Mode

all input signals are timed from VIL to 70% of $V_{pull-up}$, $1.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$, and $1.7\text{ V} \leq V_{pull-up} \leq V_{DD}$

| | | MIN | NOM | MAX | UNIT |
|-------------|--|------|-----|-----|---------------|
| f_{SCLK} | SCL frequency | | | 400 | kHz |
| t_{BUF} | Bus free time between stop and start conditions | 1.3 | | | μs |
| t_{HDSTA} | Hold time after repeated start | 0.6 | | | μs |
| t_{SUSTA} | Repeated start setup time | 0.6 | | | μs |
| t_{SUSTO} | Stop condition setup time | 0.6 | | | μs |
| t_{HDDAT} | Data hold time | 0 | | | ns |
| t_{SUDAT} | Data setup time | 100 | | | ns |
| t_{LOW} | SCL clock low period | 1300 | | | ns |
| t_{HIGH} | SCL clock high period | 600 | | | ns |
| t_F | Clock and data fall time | | | 300 | ns |
| t_R | Clock and data rise time | | | 300 | ns |
| t_{VDDAT} | Data valid time, $R = 360\ \Omega$, $C_{trace} = 23\text{ pF}$, $C_{probe} = 10\text{ pF}$ | | | 0.9 | μs |
| t_{VDACK} | Data valid acknowledge time, $R = 360\ \Omega$, $C_{trace} = 23\text{ pF}$, $C_{probe} = 10\text{ pF}$ | | | 0.9 | μs |

6.9 Timing Requirements: I²C Fast Mode Plus

all input signals are timed from VIL to 70% of $V_{pull-up}$, $1.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$, and $1.7\text{ V} \leq V_{pull-up} \leq V_{DD}$

| | | MIN | NOM | MAX | UNIT |
|-------------|--|------|-----|------|---------------|
| f_{SCLK} | SCL frequency | | | 1 | MHz |
| t_{BUF} | Bus free time between stop and start conditions | 0.5 | | | μs |
| t_{HDSTA} | Hold time after repeated start | 0.26 | | | μs |
| t_{SUSTA} | Repeated start setup time | 0.26 | | | μs |
| t_{SUSTO} | Stop condition setup time | 0.26 | | | μs |
| t_{HDDAT} | Data hold time | 0 | | | ns |
| t_{SUDAT} | Data setup time | 50 | | | ns |
| t_{LOW} | SCL clock low period | 0.5 | | | μs |
| t_{HIGH} | SCL clock high period | 0.26 | | | μs |
| t_F | Clock and data fall time | | | 120 | ns |
| t_R | Clock and data rise time | | | 120 | ns |
| t_{VDDAT} | Data valid time, $R = 360\ \Omega$, $C_{trace} = 23\text{ pF}$, $C_{probe} = 10\text{ pF}$ | | | 0.45 | μs |
| t_{VDACK} | Data valid acknowledge time, $R = 360\ \Omega$, $C_{trace} = 23\text{ pF}$, $C_{probe} = 10\text{ pF}$ | | | 0.45 | μs |

6.10 Timing Requirements: SPI Write Operation

all input signals are specified with $t_r = t_f = 1 \text{ V/ns}$ (10% to 90% of V_{IO}) and timed from a voltage level of $(V_{IL} + V_{IH}) / 2$, $1.7 \text{ V} \leq V_{IO} \leq 5.5 \text{ V}$, $1.7 \text{ V} \leq V_{DD} \leq 5.5 \text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$

| | | MIN | NOM | MAX | UNIT |
|-----------------------|--|-----|-----|-----|---------------|
| f_{SCLK} | Serial clock frequency | | | 50 | MHz |
| t_{SCLKHIGH} | SCLK high time | 9 | | | ns |
| t_{SCLKLOW} | SCLK low time | 9 | | | ns |
| t_{SDIS} | SDI setup time | 8 | | | ns |
| t_{SDIH} | SDI hold time | 8 | | | ns |
| t_{CSS} | $\overline{\text{SYNC}}$ to SCLK falling edge setup time | 18 | | | ns |
| t_{CSH} | SCLK falling edge to $\overline{\text{SYNC}}$ rising edge | 10 | | | ns |
| t_{CSHIGH} | $\overline{\text{SYNC}}$ high time | 50 | | | ns |
| t_{DACWAIT} | Sequential update wait time (time between subsequent $\overline{\text{SYNC}}$ rising edges) for same channel | 2 | | | μs |

6.11 Timing Requirements: SPI Read and Daisy Chain Operation (FSDO = 0)

all input signals are specified with $t_r = t_f = 1 \text{ V/ns}$ (10% to 90% of V_{IO}) and timed from a voltage level of $(V_{IL} + V_{IH}) / 2$, $1.7 \text{ V} \leq V_{IO} \leq 5.5 \text{ V}$, $1.7 \text{ V} \leq V_{DD} \leq 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, and $\text{FSDO} = 0$

| | | MIN | NOM | MAX | UNIT |
|-----------------------|--|-----|-----|------|---------------|
| f_{SCLK} | Serial clock frequency | | | 1.25 | MHz |
| t_{SCLKHIGH} | SCLK high time | 350 | | | ns |
| t_{SCLKLOW} | SCLK low time | 350 | | | ns |
| t_{SDIS} | SDI setup time | 8 | | | ns |
| t_{SDIH} | SDI hold time | 8 | | | ns |
| t_{CSS} | $\overline{\text{SYNC}}$ to SCLK falling edge setup time | 400 | | | ns |
| t_{CSH} | SCLK falling edge to $\overline{\text{SYNC}}$ rising edge | 400 | | | ns |
| t_{CSHIGH} | $\overline{\text{SYNC}}$ high time | 1 | | | μs |
| t_{SDODLY} | SCLK rising edge to SDO falling edge, $I_{OL} \leq 5 \text{ mA}$, $C_L = 20 \text{ pF}$ | | | 300 | ns |

6.12 Timing Requirements: SPI Read and Daisy Chain Operation (FSDO = 1)

all input signals are specified with $t_r = t_f = 1 \text{ V/ns}$ (10% to 90% of V_{IO}) and timed from a voltage level of $(V_{IL} + V_{IH}) / 2$, $1.7 \text{ V} \leq V_{IO} \leq 5.5 \text{ V}$, $1.7 \text{ V} \leq V_{DD} \leq 5.5 \text{ V}$, $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, and $\text{FSDO} = 1$

| | | MIN | NOM | MAX | UNIT |
|-----------------------|--|-----|-----|-----|---------------|
| f_{SCLK} | Serial clock frequency | | | 2.5 | MHz |
| t_{SCLKHIGH} | SCLK high time | 175 | | | ns |
| t_{SCLKLOW} | SCLK low time | 175 | | | ns |
| t_{SDIS} | SDI setup time | 8 | | | ns |
| t_{SDIH} | SDI hold time | 8 | | | ns |
| t_{CSS} | $\overline{\text{SYNC}}$ to SCLK falling edge setup time | 300 | | | ns |
| t_{CSH} | SCLK falling edge to $\overline{\text{SYNC}}$ rising edge | 300 | | | ns |
| t_{CSHIGH} | $\overline{\text{SYNC}}$ high time | 1 | | | μs |
| t_{SDODLY} | SCLK rising edge to SDO falling edge, $I_{OL} \leq 5 \text{ mA}$, $C_L = 20 \text{ pF}$ | | | 300 | ns |

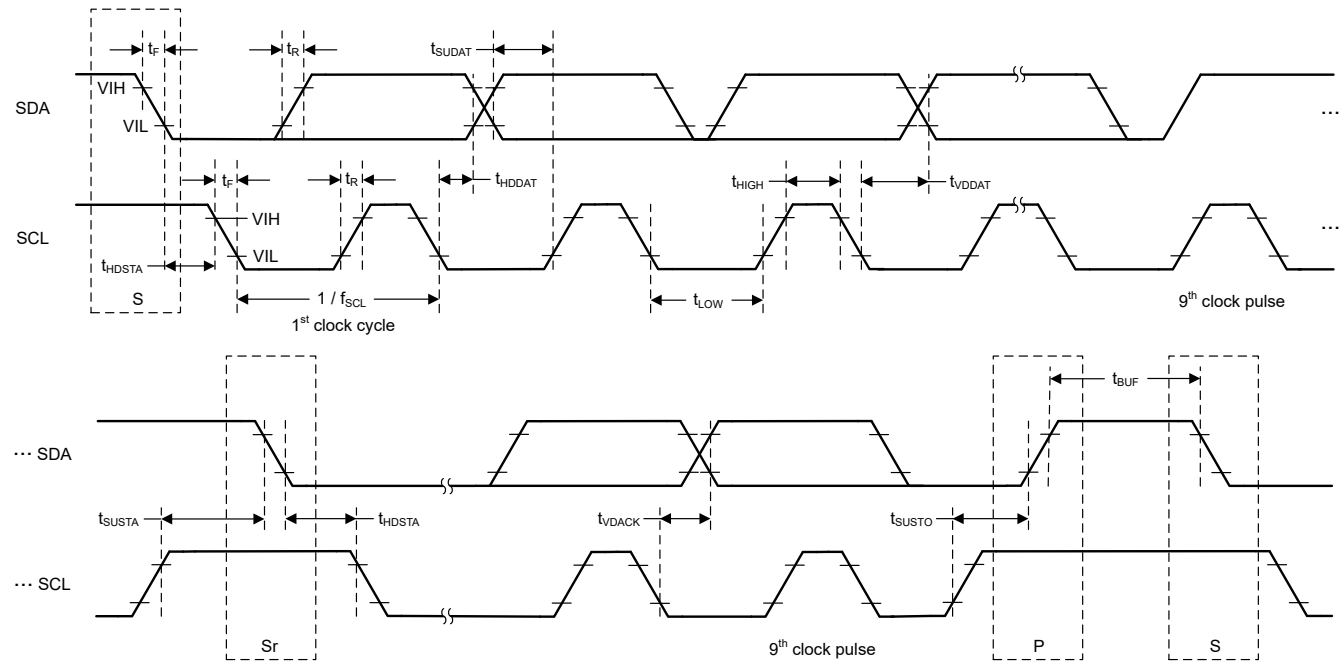
6.13 Timing Requirements: PWM Output

all input signals are timed from VIL to 70% of $V_{\text{pull-up}}$, $1.7\text{ V} \leq V_{\text{DD}} \leq 5.5$, $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$, and $1.7\text{ V} \leq V_{\text{pull-up}} \leq V_{\text{DD}}$

| | | MIN | NOM | MAX | UNIT |
|----------------------|------------------------------|-------|-----|--------|---------------|
| f_{PWMOUT} | PWM frequency ⁽¹⁾ | 0.218 | | 48.828 | kHz |
| t_{PWMOHI} | PWM high time | 1 | | | μs |
| t_{PWMOLO} | PWM low time | 1 | | | μs |
| t_{PWMDUTY} | PWM duty cycle | 0 | | 100 | % |

(1) The frequency range does not account for the internal oscillator frequency error.

6.14 Timing Diagrams



S: Start bit, Sr: Repeated start bit, P: Stop bit

FIG 6-1. I²C Timing Diagram

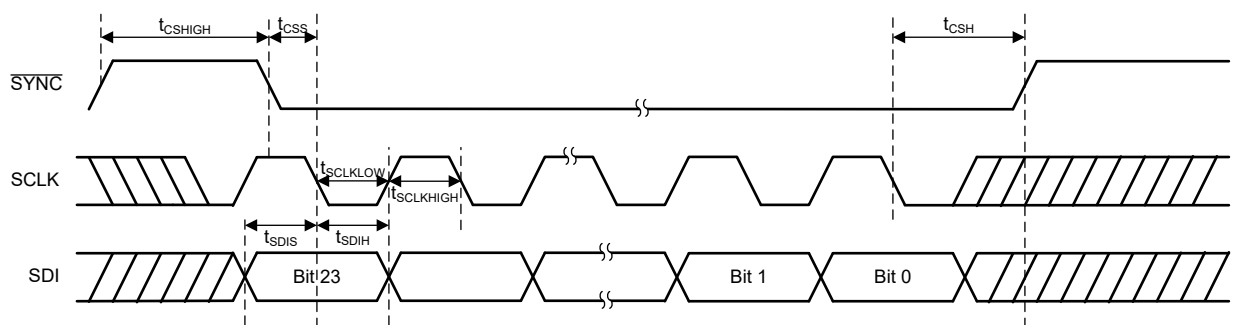


FIG 6-2. SPI Write Timing Diagram

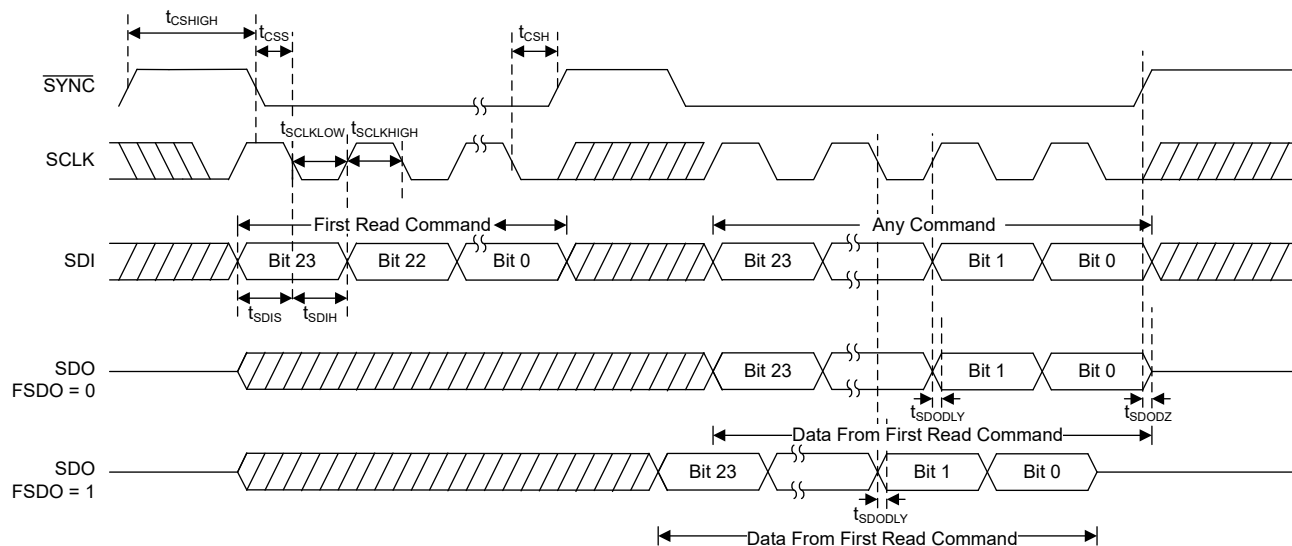


图 6-3. SPI Read Timing Diagram

6.15 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, external reference = 5.5 V , and gain = $1 \times$ (unless otherwise noted)

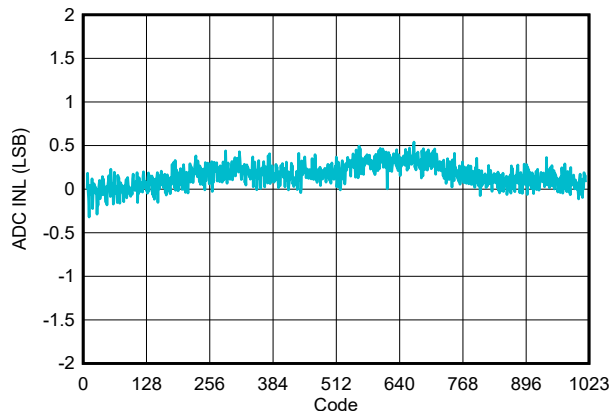


图 6-4. ADC INL vs Digital Output Code

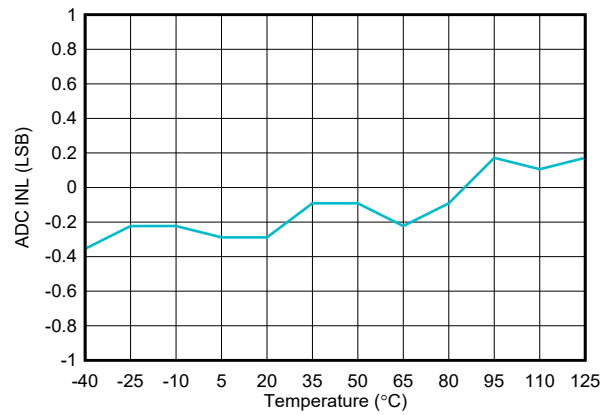


图 6-5. ADC INL vs Temperature

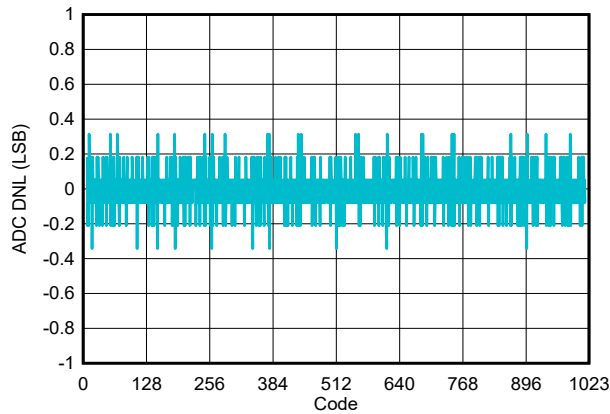


图 6-6. ADC DNL vs Digital Output Code

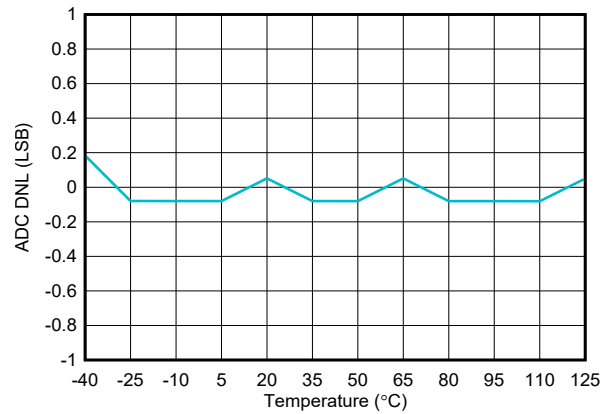


图 6-7. ADC DNL vs Temperature

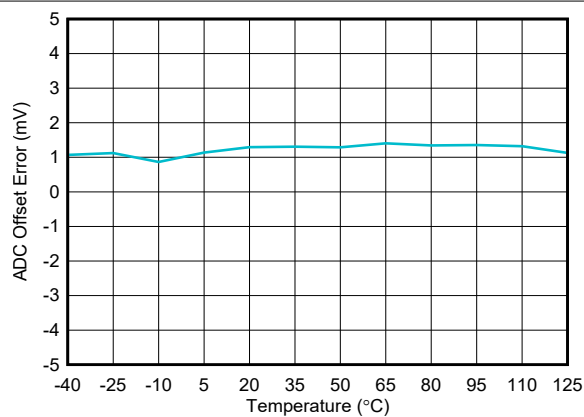


图 6-8. ADC Offset Error vs Temperature

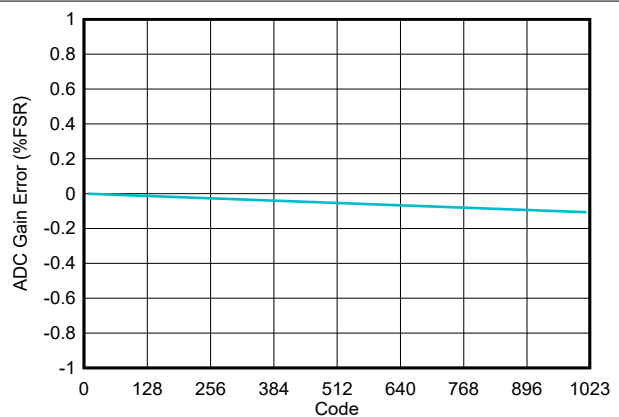


图 6-9. ADC Gain Error vs Digital Output Code

6.15 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{DD} = 5.5\text{ V}$, external reference = 5.5 V , and gain = $1 \times$ (unless otherwise noted)

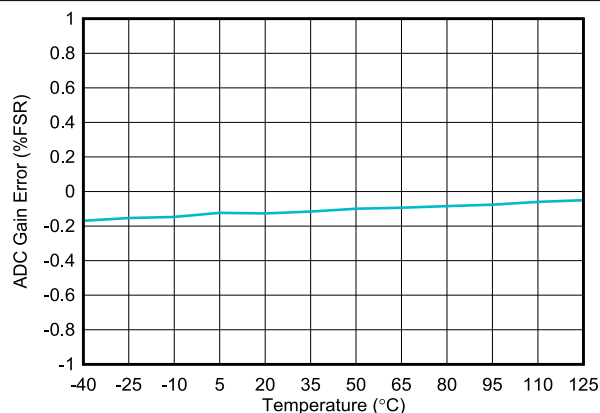


Figure 6-10. ADC Gain Error vs Temperature

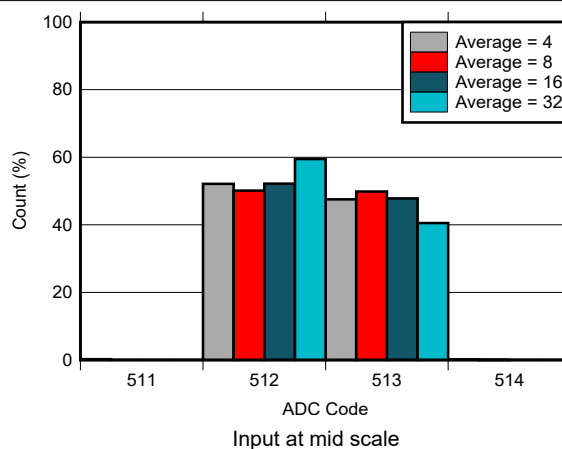


Figure 6-11. ADC Count vs Digital Output Code

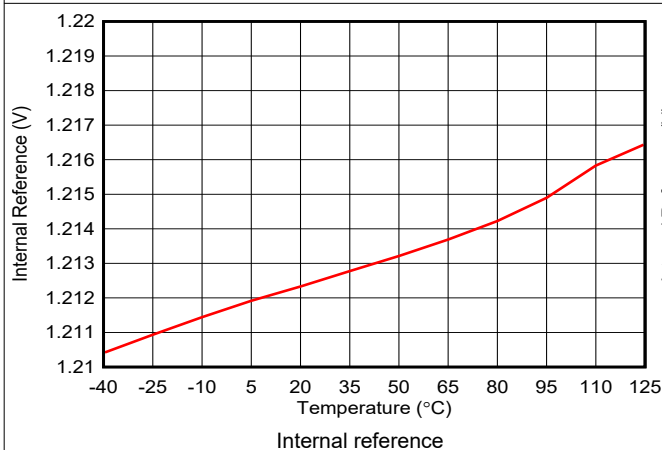


Figure 6-12. Internal Reference vs Temperature

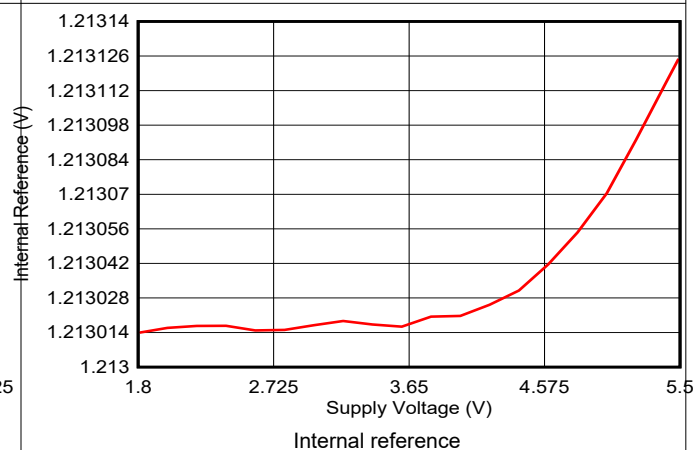


Figure 6-13. Internal Reference vs Supply Voltage

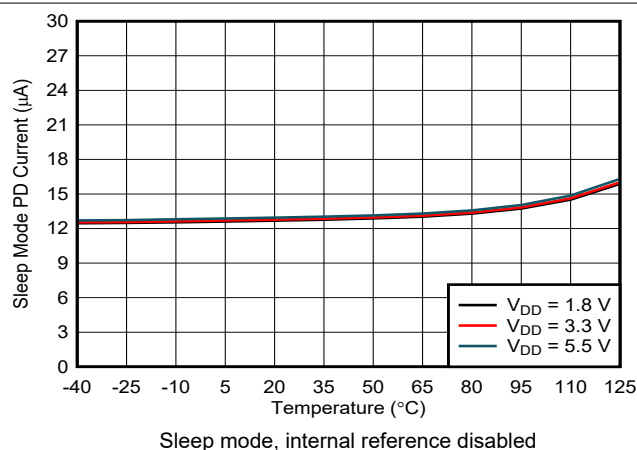


Figure 6-14. Power-Down Current vs Temperature

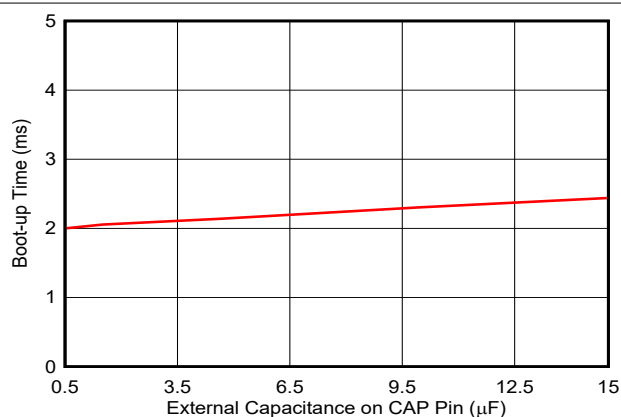


Figure 6-15. Boot-Up Time vs Capacitance on CAP pin

7 Detailed Description

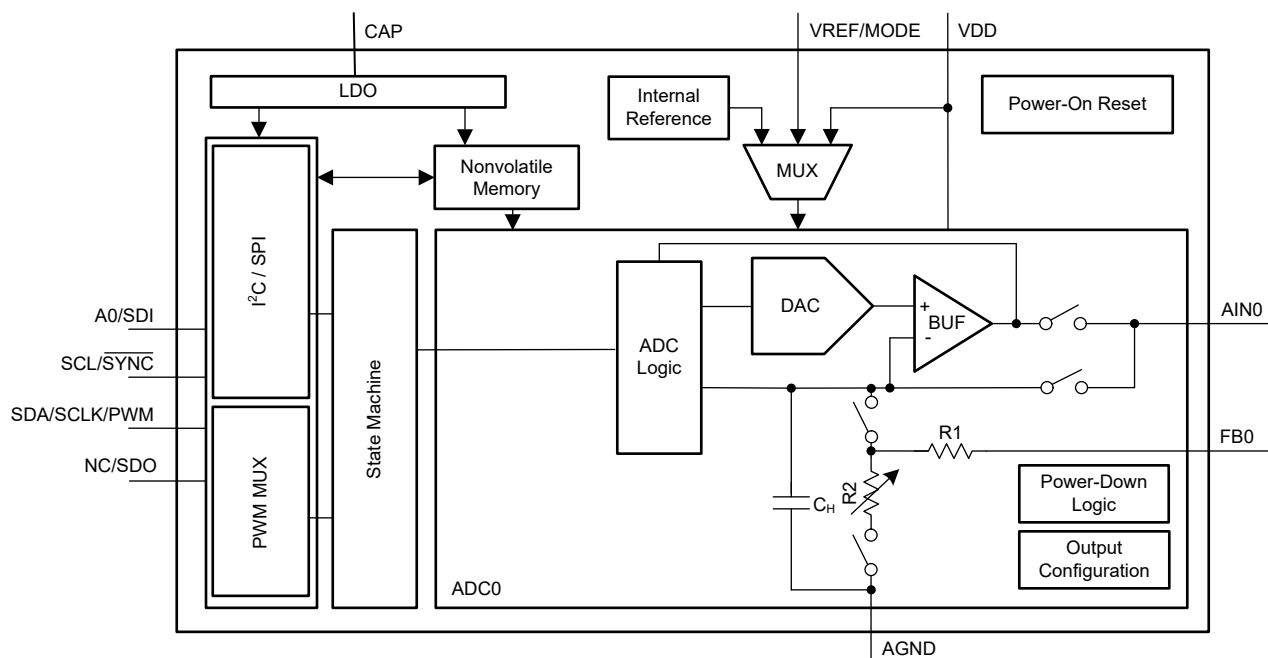
7.1 Overview

The AFE539F1-Q1 is a 10-bit smart analog front end (AFE) with PWM output and ADC input. The SDA/SCLK pin is re-purposed as the PWM output when the VREF/MODE pin is held high.

The AFE539F1-Q1 provides a preprogrammed state machine that functions as a constant power-dissipation or heating controller. This device contains nonvolatile memory (NVM), an internal reference, automatically detects I²C and SPI, and a general-purpose input. The device supports Hi-Z power-down modes by default, which can be configured to 10 k Ω -AGND or 100 k Ω -AGND using the NVM. The AFE539F1-Q1 has a power-on-reset (POR) circuit that makes sure all the registers start with default or user-programmed settings using NVM. The AFE539F1-Q1 operates with either an internal reference, external reference, or with power supply as the reference.

The AFE539F1-Q1 supports I²C standard mode (100Kbps), fast mode (400Kbps), and fast mode plus (1Mbps). The I²C interface can be configured with four device addresses using the A0 pin. The SPI mode supports a three-wire interface by default, with up to 25-MHz SCLK input. The NC/SDO input can be configured as SDO in the NVM for SPI read capability. The AFE539F1-Q1 is designed for constant power dissipation in automotive DC-link capacitor discharge circuits and constant power heating applications. The state machine and NVM enable *processor-less* operation. Because of the *smart* feature set, the AFE539F1-Q1 is called a smart AFE.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Smart Analog Front End (AFE) Architecture

The AFE539F1-Q1 smart analog front end (AFE) consists of a 10-bit analog-to-digital converter (ADC) input and a 7-bit duty-cycle pulse-width modulation (PWM) output. The ADC uses a successive-approximation register (SAR) architecture. The DAC inside the ADC uses a string architecture. The PWM output is multiplexed with one of the digital interface pins. セクション 7.2 shows the smart AFE architecture within the block diagram, which operates from a 1.8-V to 5.5-V power supply. The device has an internal voltage reference of 1.21 V. There is an option to select an external reference on the VREF/MODE pin or use the power supply as a reference. The ADC uses one of these three reference options.

The AFE539F1-Q1 features a preprogrammed state machine supporting constant power-dissipation control operation. 図 7-1 shows the digital architecture of the smart AFE with the interconnections between different functional blocks. This state machine allows the user to program the coefficients and input-output parameters. The state machine can be disabled by writing to the STATE-MACHINE-CONFIG0 register. The user configurations are stored in the NVM and the state machine can be operated in standalone mode without interfacing to a processor (*processor-less operation*).

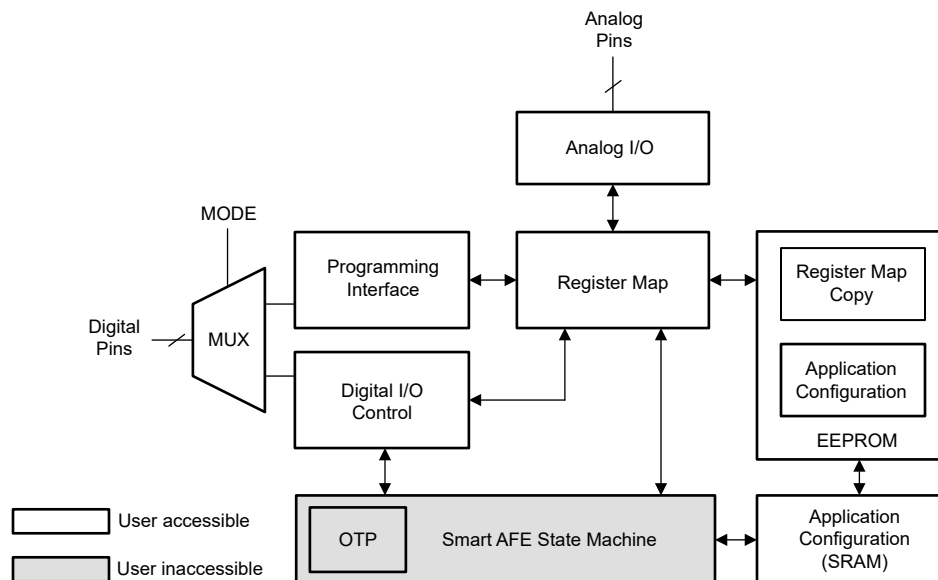


図 7-1. Smart AFE Architecture

7.3.2 Programming Interface

The AFE539F1-Q1 have five digital I/O pins that control I²C, SPI, PWM, and mode selection. The VREF/MODE pin must be at logic low to enable the programming interface. These devices automatically detect I²C and SPI protocols at the first successful communication after power-on, and then connect to the detected interface. After an interface protocol is connected, any change in the protocol is ignored. The I²C interface uses the A0 pin to select from among four address options. The SPI is a three-wire interface by default. No readback capability is available in three-wire SPI mode. The NC/SDO pin can be configured as the SDO function in the register map and then programmed into the NVM. With the NC/SDO pin acting as SDO, the SPI works as a four-wire interface. The SPI readback mode is slower than the write mode. The programming interface pins are:

- I²C: SCL, SDA, A0
- SPI: SCLK, SDI, $\overline{\text{SYNC}}$, NC/SDO

All the digital pins are open drain when used as outputs. Therefore, all the output pins must be pulled up to the desired I/O voltage using external resistors.

7.3.3 Nonvolatile Memory (NVM)

The AFE539F1-Q1 contain nonvolatile memory (NVM) bits. These memory bits are user programmable and erasable, and retain set values in the absence of a power supply. The highlighted gray cells in the *Register Map* show all the register bits that can be stored in the NVM by setting NVM-PROG = 1 in the COMMON-TRIGGER register. The NVM-PROG bit autoresets. The NVM-BUSY bit in the GENERAL-STATUS register is set to 1 by the device when an NVM write or reload operation is ongoing. During this time, the device blocks all read and write operations from and to the device. The NVM-BUSY bit is set to 0 after the write or reload operation is complete; at this point, all read and write operations from and to the device are allowed. The default value for all the registers in the AFE539F1-Q1 is loaded from NVM as soon as a POR event is issued.

The AFE539F1-Q1 also implements a NVM-RELOAD bit in the COMMON-TRIGGER register. Set this bit to 1 for the device to start an NVM-reload operation. The NVM-reload operation overwrites the register map with the stored data from the NVM. After completion, the device autoresets this bit to 0. During the NVM-RELOAD operation, the NVM-BUSY bit is set to 1.

7.3.3.1 NVM Cyclic Redundancy Check (CRC)

The AFE539F1-Q1 implements a cyclic redundancy check (CRC) feature for the NVM to make sure that the data stored in the NVM is uncorrupted. There are two types of CRC alarm bits implemented in the AFE539F1-Q1:

- NVM-CRC-FAIL-USER
- NVM-CRC-FAIL-INT

The NVM-CRC-FAIL-USER bit indicates the status of user-programmable NVM bits, and the NVM-CRC-FAIL-INT bit indicates the status of internal NVM bits. The CRC feature is implemented by storing a 16-bit CRC (CRC-16-CCITT) along with the NVM data each time the NVM program operation (write or reload) is performed and during the device boot up. The device reads the NVM data and validates the data with the stored CRC. The CRC alarm bits (NVM-CRC-FAIL-USER and NVM-CRC-FAIL-INT in the GENERAL-STATUS register) report any errors after the data are read from the device NVM. The alarm bits are set only at boot up.

7.3.3.1.1 NVM-CRC-FAIL-USER Bit

A logic 1 on NVM-CRC-FAIL-USER bit indicates that the user-programmable NVM data are corrupt. During this condition, all registers in the device are initialized with factory reset values, and any registers can be written to or read from. To reset the alarm bits to 0, issue a software reset (see [セクション 7.3.5](#)) command, or cycle power to the device. A software reset or power-cycle also reloads the user-programmable NVM bits. In case the failure persists, reprogram the NVM.

7.3.3.1.2 NVM-CRC-FAIL-INT Bit

A logic 1 on NVM-CRC-FAIL-INT bit indicates that the internal NVM data are corrupt. During this condition, all registers in the device are initialized with factory reset values, and any registers can be written to or read from. In case of a temporary failure, to reset the alarm bits to 0, issue a software reset (see [セクション 7.3.5](#)) command or cycle power to the device. A permanent failure in the NVM makes the device unusable.

7.3.4 Power-On Reset (POR)

The AFE539F1-Q1 includes a power-on reset (POR) function that controls the output voltage at power up. After the V_{DD} supply has been established, a POR event is issued. The POR causes all registers to initialize to default values, and communication with the device is valid only after a POR (boot-up) delay. The default value for all the registers in the AFE539F1-Q1 is loaded from NVM as soon as the POR event is issued.

When the device powers up, a POR circuit sets the device to the default mode. The POR circuit requires specific V_{DD} levels, as indicated in [Figure 7-2](#), to make sure that the internal capacitors discharge and reset the device at power up. To make sure that a POR occurs, V_{DD} must be less than 0.7 V for at least 1 ms. When V_{DD} drops to less than 1.65 V, but remains greater than 0.7 V (shown as the undefined region), the device may or may not reset under all specified temperature and power-supply conditions. In this case, initiate a POR. When V_{DD} remains greater than 1.65 V, a POR does not occur.

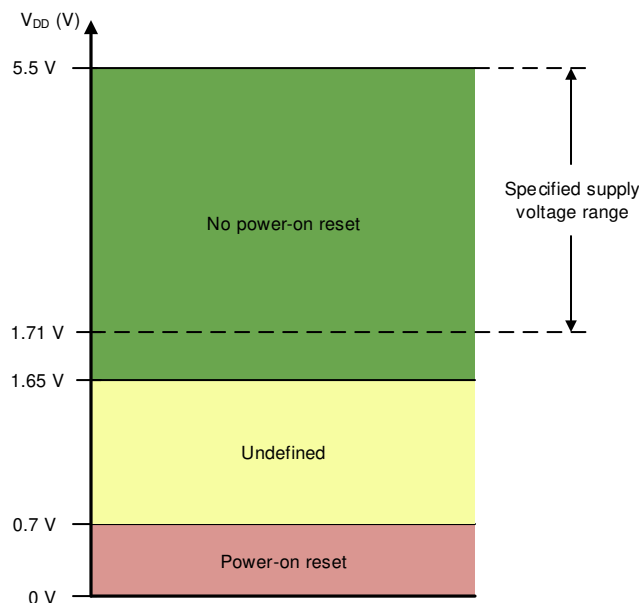


Figure 7-2. Threshold Levels for V_{DD} POR Circuit

7.3.5 External Reset

An external reset to the device can be triggered through the register map. To initiate a device software reset event, write the reserved code 1010b to the RESET field in the COMMON-TRIGGER register. A software reset initiates a POR event.

7.3.6 Register-Map Lock

The AFE539F1-Q1 implements a register-map lock feature that prevents an accidental or unintended write to the registers. The device locks all the registers when the DEV-LOCK bit in the COMMON-CONFIG register is set to 1. However, the software reset function through the COMMON-TRIGGER register is not blocked when using I²C interface. To bypass the DEV-LOCK setting, write 0101b to the DEV-UNLOCK bits in the COMMON-TRIGGER register.

7.4 Device Functional Modes

7.4.1 Analog-to-Digital Converter (ADC) Mode

Channel 0 of the AFE539F1-Q1 acts as an ADC. The ADC is controlled by the state-machine in this device. The transfer function of the ADC is given in 式 1.

$$\text{ADC_DATA} = \left(\text{INTEGER} \right) \left(\frac{V_{\text{IN}}}{V_{\text{FS}}} \right) \times 2^N \quad (1)$$

where:

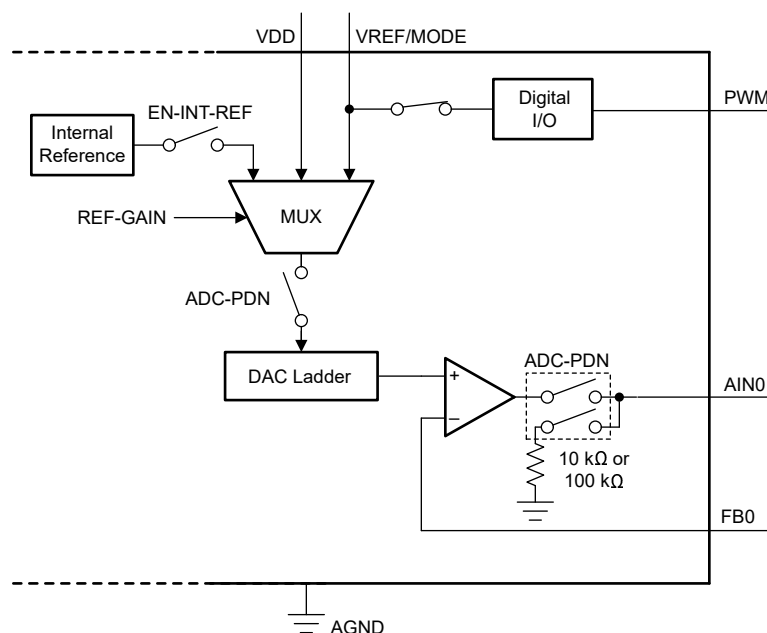
- ADC_DATA is the output of the ADC available to the state machine and is limited to $(2^N - 1)$.
- V_{IN} is the input voltage at the AIN0 pin.
- V_{FS} is the full-scale input voltage, as provided in 表 7-1.
- N is the number of ADC bits = 10.
- INTEGER denotes integer division.

表 7-1. Full Scale Analog Input (V_{FS})

| REFERENCE (VREF) | GAIN | V_{FS} |
|------------------|-------|-------------------|
| Power supply | 1 × | VDD / 3 |
| External | 1 × | VREF / 3 |
| Internal | 1.5 × | (VREF × GAIN) / 3 |
| | 2 × | (VREF × GAIN) / 3 |
| | 3 × | (VREF × GAIN) / 6 |
| | 4 × | (VREF × GAIN) / 6 |

7.4.1.1 Voltage Reference Selection

☒ 7-3 shows the three possible voltage reference options with the AFE539F1-Q1: the power supply as reference, internal reference, or external reference (VREF/MODE pin). The REF-GAIN field in the REF-GAIN-CONFIG register selects the reference and the respective gain. The full scale ADC voltage changes based on the voltage reference selection.



☒ 7-3. Voltage Reference Selection and Power-Down Logic

7.4.1.1.1 Power-Supply as Reference

By default, the AFE539F1-Q1 operates with the power-supply pin (VDD) as a reference. The gain at the output stage is always 1 ×.

7.4.1.1.2 Internal Reference

The AFE539F1-Q1 contains an internal reference. To enable the internal reference, write 1 to the EN-INT-REF bit in the COMMON-CONFIG register. The internal reference generates a fixed 1.21-V voltage (typical). Use the REF-GAIN field in the REF-GAIN-CONFIG register to select the internal reference and also to achieve gains of 1.5 ×, 2 ×, 3 ×, or 4 × for the ADC full scale voltage (V_{FS}).

7.4.1.1.3 External Reference

The AFE539F1-Q1 provides an external reference input. Select the external reference option by configuring the REF-GAIN field in the REF-GAIN-CONFIG register appropriately. The external reference can be between 1.8 V and VDD.

注

The external reference must be less than VDD in both transient and steady-state conditions. Therefore, the external reference must ramp up after VDD and ramp down before VDD.

7.4.2 Pulse-Width Modulation (PWM) Mode

The AFE539F1-Q1 provides the 7-bit duty-cycle PWM output on the SDA/SCLK/PWM pin. Pull the VREF/MODE pin high to enable PWM functionality. 表 7-2 lists all the possible PWM frequency configurations using the PWM-FREQ bits in the PWM-FREQUENCY SRAM register.

表 7-2. PWM Frequency Configuration

| SRAM REGISTER | PWM-FREQ BIT FIELD | PWM FREQUENCY (kHz) | DUTY CYCLE (%) FOR CODE 1 | DUTY CYCLE (%) FOR CODE 126 |
|-------------------------------|--------------------|---------------------|---------------------------|-----------------------------|
| PWM-FREQUENCY (0x23 [4:0]) | 0 | Invalid | N/A | N/A |
| | 1 | 48.828 | 4.88 | 95.12 |
| | 2 | 24.414 | 2.44 | 97.56 |
| | 3 | 16.276 | 1.63 | 98.37 |
| | 4 | 12.207 | 1.22 | 98.44 |
| | 5 | 8.138 | 0.81 | 98.44 |
| | 6 | 6.104 | 0.78 | 98.44 |
| | 7 | 3.052 | 0.78 | 98.44 |
| | 8 | 2.035 | 0.78 | 98.44 |
| | 9 | 1.526 | 0.78 | 98.44 |
| | 10 | 1.221 | 0.78 | 98.44 |
| | 11 | 1.017 | 0.78 | 98.44 |
| | 12 | 0.872 | 0.78 | 98.44 |
| | 13 | 0.763 | 0.78 | 98.44 |
| | 14 | 0.678 | 0.78 | 98.44 |
| | 15 | 0.610 | 0.78 | 98.44 |
| | 16 | 0.555 | 0.78 | 98.44 |
| | 17 | 0.509 | 0.78 | 98.44 |
| | 18 | 0.470 | 0.78 | 98.44 |
| | 19 | 0.436 | 0.78 | 98.44 |
| | 20 | 0.407 | 0.78 | 98.44 |
| | 21 | 0.381 | 0.78 | 98.44 |
| | 22 | 0.359 | 0.78 | 98.44 |
| | 23 | 0.339 | 0.78 | 98.44 |
| | 24 | 0.321 | 0.78 | 98.44 |
| | 25 | 0.305 | 0.78 | 98.44 |
| | 26 | 0.291 | 0.78 | 98.44 |
| | 27 | 0.277 | 0.78 | 98.44 |
| | 28 | 0.265 | 0.78 | 98.44 |
| | 29 | 0.254 | 0.78 | 98.44 |
| | 30 | 0.244 | 0.78 | 98.44 |
| | 31 | 0.218 | 0.78 | 98.44 |

The duty cycle of the PWM is proportional to the 7-bit code, 0d to 126d. As 表 7-3 shows, the code 127d corresponds to 100% duty cycle. The duty cycle 99.22% (127d/128d) is skipped to achieve 100% duty cycle using a 7-bit code. The PWM duty-cycle setting is done by the state machine and is not exposed to the user.

表 7-3. PWM Duty Cycle Setting

| CODE | DUTY-CYCLE | DESCRIPTION |
|------|------------|--|
| 0 | 0% | Always 0 |
| 1 | 0.78% | Minimum linear duty cycle |
| x | (x/128)% | x is the code between 2d and 125d, both included |
| 126 | 98.44% | Maximum linear duty cycle |

表 7-3. PWM Duty Cycle Setting (continued)

| CODE | DUTY-CYCLE | DESCRIPTION |
|------|------------|---|
| 127 | 100% | Always 1. The duty cycle 99.22% (127d/128d) is skipped. |

7.4.3 Constant Power-Dissipation Control

The AFE539F1-Q1 can be used in applications where constant power dissipation is desired on a resistive load independently on applied voltage. Power dissipation in a fixed resistive load is inversely proportional to the resistance. When the voltage across the resistance varies, for example, in a discharging circuit, constant power can be achieved by modulating the effective resistance seen by the discharge circuit. [Figure 7-4](#) shows an example circuit to create a variable effective resistance from a fixed resistive load using a PWM signal. The effective resistance is the load resistance divided by the PWM duty cycle.

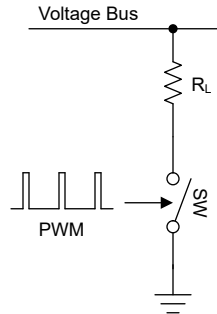


Figure 7-4. PWM-modulated Resistor

The AFE539F1-Q1 generates a PWM signal with a duty cycle dependent on the voltage applied to the ADC input. The AFE539F1-Q1 has a 10-bit ADC input with selectable reference voltage (V_{REF}). The AFE539F1-Q1 calculates the PWM duty cycle so that a constant dissipated power of the resistor is maintained.

The AFE539F1-Q1 runs a PWM duty cycle update loop that sets the duty cycle (D) according to [Equation 2](#).

$$D = \frac{K \times 2^{15}}{(ADC_DATA)^2} = \frac{K \times (V_{FS})^2}{(V_{IN})^2 \times 2^5} \quad (2)$$

where:

- ADC_DATA is the decimal equivalent of the output from the ADC available to the state machine.
- V_{IN} is the ADC input voltage.
- V_{FS} is the full-scale ADC input voltage, as listed in [Table 7-1](#).
- K is a user-configurable function-coefficient with a value of 16-bit integer (range: 1 to 65535) as programmed in the FUNCTION-COEFFICIENT register.

The duty cycle of the PWM output of the AFE539F1-Q1 has 7-bit resolution which means the minimum duty cycle as well as the step size is about 0.78%. The PWM can achieve 100% saturation, the lower and upper PWM value limit is user-configurable as well to accommodate specific application requirements. The constant power achieved with this pulse-width modulated resistor can be expressed accordingly as [Equation 3](#).

$$P_{const} = \frac{K_2 \times (V_{FS})^2}{R_L} \quad (3)$$

where:

- R_L is the load resistance.
- K_2 is a constant that is a function of the function-coefficient, K and the attenuation factor between the bus voltage and the full-scale ADC input.

[Equation 3](#) expresses that the theoretical constant power is independent on the input voltage. The power depends on the load resistance value and value of the constant, K_2 . However, the PWM is updated in discrete steps, the calculated constant power is in reality a power limit.

7.5 Programming

7.5.1 SPI Programming Mode

An SPI access cycle for AFE539F1-Q1 is initiated by asserting the $\overline{\text{SYNC}}$ pin low. The serial clock, SCLK, can be a continuous or gated clock. SDI data are clocked on SCLK falling edges. The SPI frame for AFE539F1-Q1 is 24 bits long. Therefore, the $\overline{\text{SYNC}}$ pin must stay low for at least 24 SCLK falling edges. The access cycle ends when the $\overline{\text{SYNC}}$ pin is deasserted high. If the access cycle contains less than the minimum clock edges, the communication is ignored. By default, the SDO pin is not enabled (three-wire SPI). In the three-wire SPI mode, if the access cycle contains more than the minimum clock edges, only the first 24 bits are used by the device. When $\overline{\text{SYNC}}$ is high, the SCLK and SDI signals are blocked, and SDO becomes Hi-Z to allow data readback from other devices connected on the bus.

表 7-4 and 図 7-5 describe the format for the 24-bit SPI access cycle. The first byte input to SDI is the instruction cycle. The instruction cycle identifies the request as a read or write command and the 7-bit address that is to be accessed. The last 16 bits in the cycle form the data cycle.

表 7-4. SPI Read/Write Access Cycle

| BIT | FIELD | DESCRIPTION |
|-------|----------|---|
| 23 | R/W | Identifies the communication as a read or write command to the address register: R/W = 0 sets a write operation. R/W = 1 sets a read operation |
| 22-16 | A[6:0] | Register address: specifies the register to be accessed during the read or write operation |
| 15-0 | DI[15:0] | Data cycle bits: If a write command, the data cycle bits are the values to be written to the register with address A[6:0]. If a read command, the data cycle bits are <i>don't care</i> values. |

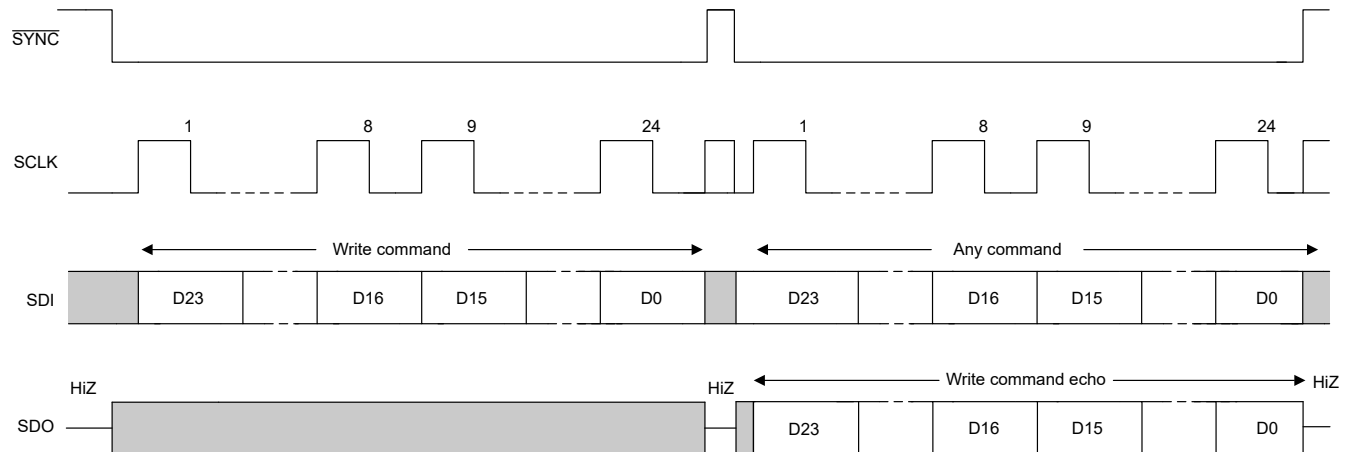


図 7-5. SPI Write Cycle

Read operations require that the SDO pin is first enabled by setting the SDO-EN bit in the INTERFACE-CONFIG register. This configuration is called four-wire SPI. A read operation is initiated by issuing a read command access cycle. After the read command, a second access cycle must be issued to get the requested data. The output data format is shown in 表 7-5 and 図 7-6. Data are clocked out on the SDO pin either on the falling edge or rising edge of SCLK according to the FSDO bit, as shown in 図 6-3.

表 7-5. SDO Output Access Cycle

| BIT | FIELD | DESCRIPTION |
|-------|----------|--|
| 23 | R/W | Echo R/W from previous access cycle |
| 22-16 | A[6:0] | Echo register address from previous access cycle |
| 15-0 | DI[15:0] | Readback data requested on previous access cycle |

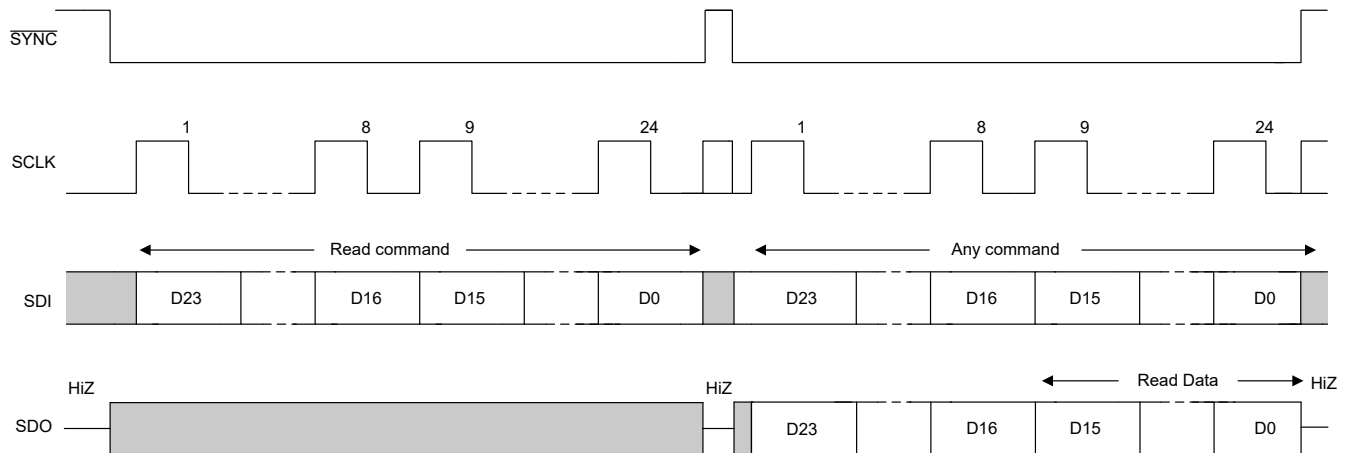


FIG 7-6. SPI Read Cycle

The daisy-chain operation is also enabled with the SDO pin. In daisy-chain mode, multiple devices are connected in a *chain* with the SDO pin of one device is connected to SDI pin of the following device, as shown in [FIG 7-7](#). The SPI host drives the SDI pin of the first device in the chain. The SDO pin of the last device in the chain is connected to the POCI pin of the SPI host. In four-wire SPI mode, if the access cycle contains multiples of 24 clock edges, only the last 24 bits are used by the device first device in the chain. If the access cycle contains clock edges that are not in multiples of 24, the SPI packet is ignored by the device. [FIG 7-8](#) describes the packet format for the daisy-chain write cycle.

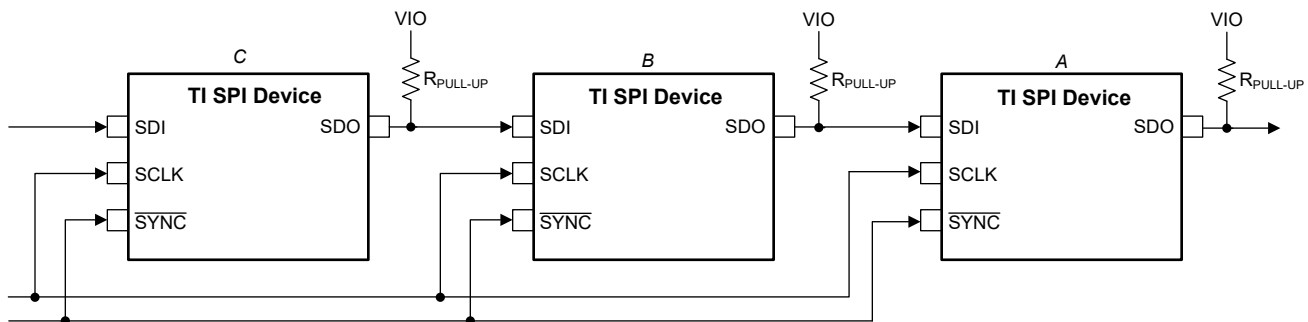


FIG 7-7. SPI Daisy-Chain Connection

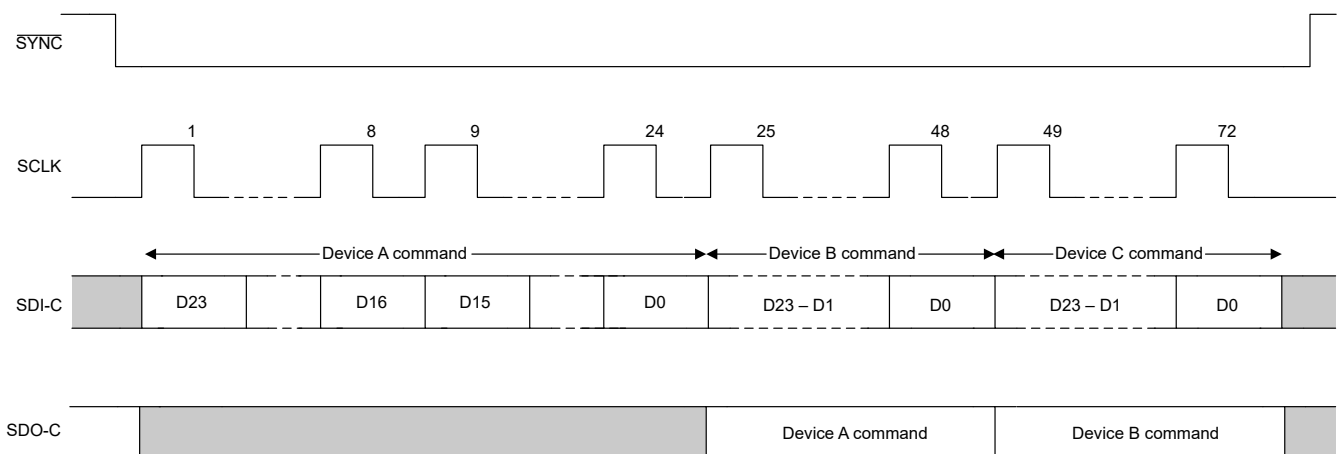


FIG 7-8. SPI Daisy-Chain Write Cycle

7.5.2 I²C Programming Mode

The AFE539F1-Q1 has a 2-wire serial interface (SCL and SDA), and one address pin (A0), as shown in the pin diagram in the *Pin Configuration and Functions* section. The I²C bus consists of a data line (SDA) and a clock line (SCL) with pullup structures. When the bus is idle, both SDA and SCL lines are pulled high. All the I²C-compatible devices connect to the I²C bus through the open drain I/O pins, SDA and SCL.

The I²C specification states that the device that controls communication is called a *controller*, and the devices that are controlled by the controller are called *targets*. The controller generates the SCL signal. The controller also generates special timing conditions (start condition, repeated start condition, and stop condition) on the bus to indicate the start or stop of a data transfer. Device addressing is completed by the controller. The controller on an I²C bus is typically a microcontroller or digital signal processor (DSP). The AFE539F1-Q1 operates as a target on the I²C bus. A target acknowledges controller commands, and upon controller control, receives or transmits data.

Typically, the AFE539F1-Q1 operates as a target receiver. A controller writes to the AFE539F1-Q1, a target receiver. However, if a controller requires the AFE539F1-Q1 internal register data, the AFE539F1-Q1 operates as a target transmitter. In this case, the controller reads from the AFE539F1-Q1. According to I²C terminology, read and write refer to the controller.

The AFE539F1-Q1 supports the following data transfer modes:

- Standard mode (100Kbps)
- Fast mode (400Kbps)
- Fast mode plus (1.0Mbps)

The data transfer protocol for standard and fast modes is exactly the same; therefore, both modes are referred to as *F/S-mode* in this document. The fast mode plus protocol is supported in terms of data transfer speed, but not output current. The low-level output current is 3 mA; similar to the case of standard and fast modes. The AFE539F1-Q1 supports 7-bit addressing. The 10-bit addressing mode is not supported. The device supports the general call reset function. Sending the following sequence initiates a software reset within the device: start or repeated start, 0x00, 0x06, stop. The reset is asserted within the device on the rising edge of the ACK bit, following the second byte.

Other than specific timing signals, the I²C interface works with serial bytes. At the end of each byte, a ninth clock cycle generates and detects an acknowledge signal. An acknowledge is when the SDA line is pulled low during the high period of the ninth clock cycle. A not-acknowledge is when the SDA line is left high during the high period of the ninth clock cycle, as shown in [Figure 7-9](#).

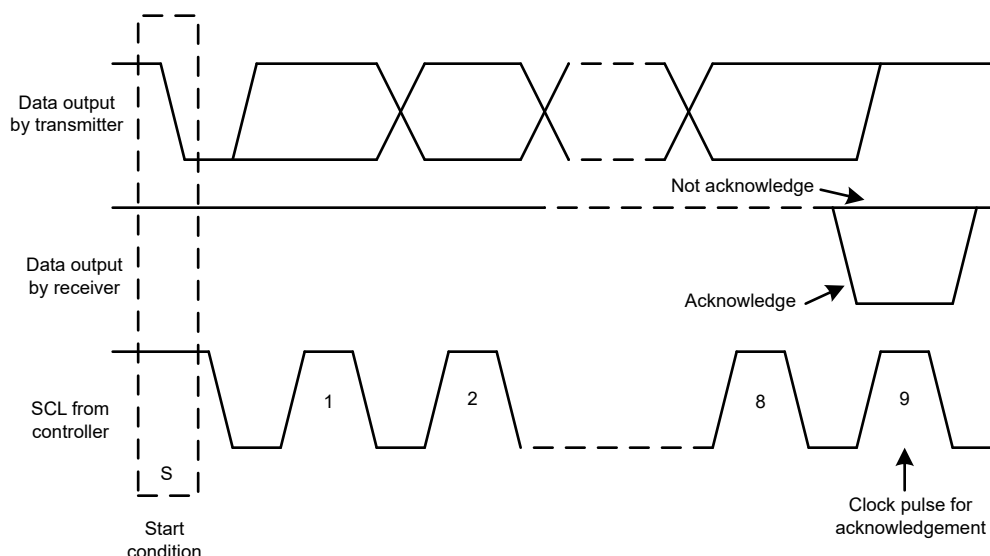


Figure 7-9. Acknowledge and Not Acknowledge on the I²C Bus

7.5.2.1 F/S Mode Protocol

The following steps explain a complete transaction in F/S mode.

1. The controller initiates data transfer by generating a start condition. The start condition is when a high-to-low transition occurs on the SDA line while SCL is high, as shown in [Figure 7-10](#). All I²C-compatible devices recognize a start condition.
2. The controller then generates the SCL pulses, and transmits the 7-bit address and the read/write direction bit (R/\overline{W}) on the SDA line. During all transmissions, the controller makes sure that data are valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse, as shown in [Figure 7-11](#). All devices recognize the address sent by the controller and compare the address to the respective internal fixed address. Only the target device with a matching address generates an acknowledge by pulling the SDA line low during the entire high period of the 9th SCL cycle, as shown in [Figure 7-9](#). When the controller detects this acknowledge, the communication link with a target has been established.
3. The controller generates further SCL cycles to transmit (R/\overline{W} bit 0) or receive (R/\overline{W} bit 1) data to the target. In either case, the receiver must acknowledge the data sent by the transmitter. The acknowledge signal can be generated by the controller or by the target, depending on which is the receiver. The 9-bit valid data sequences consists of eight data bits and one acknowledge-bit, and can continue as long as necessary.
4. To signal the end of the data transfer, the controller generates a stop condition by pulling the SDA line from low-to-high while the SCL line is high, as shown in [Figure 7-10](#). This action releases the bus and stops the communication link with the addressed target. All I²C-compatible devices recognize the stop condition. Upon receipt of a stop condition, the bus is released, and all target devices then wait for a start condition followed by a matching address.

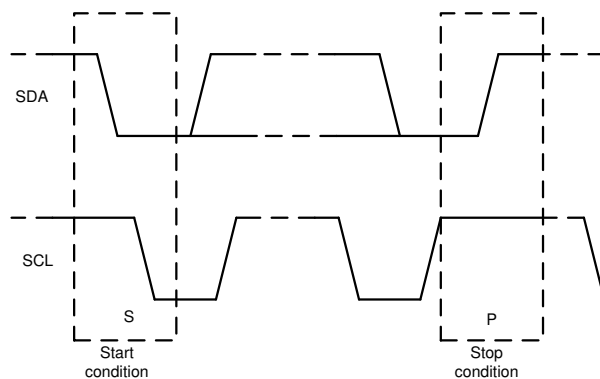


Figure 7-10. Start and Stop Conditions

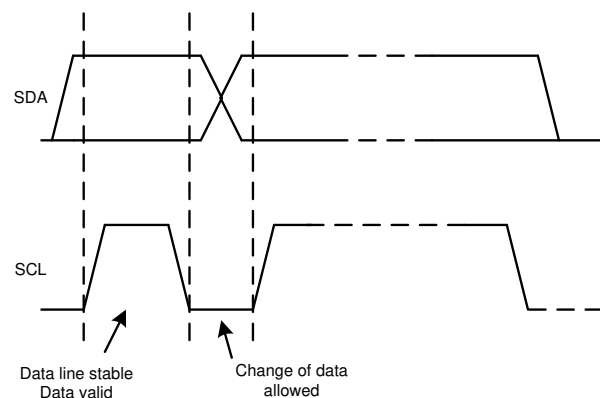


Figure 7-11. Bit Transfer on the I²C Bus

7.5.2.2 I²C Update Sequence

For a single update, the AFE539F1-Q1 requires a start condition, a valid I²C address byte, a command byte, and two data bytes, as listed in 表 7-6.

表 7-6. Update Sequence

| MSB | | LSB | ACK | MSB | ... | LSB | ACK | MSB | ... | LSB | ACK | MSB | ... | LSB | ACK |
|-------------------------------------|------|-----|-----|---------------------------------|-----|-----|-----|------------------|-----|-----|-----|------------------|-----|-----|-----|
| Address (A) byte セクション 7.5.2.2.1 | | | | Command byte セクション 7.5.2.2.2 | | | | Data byte - MSDB | | | | Data byte - LSDB | | | |
| DB [31:24] | | | | DB [23:16] | | | | DB [15:8] | | | | DB [7:0] | | | |

After each byte is received, the AFE539F1-Q1 acknowledges the byte by pulling the SDA line low during the high period of a single clock pulse, as shown in 図 7-12. These four bytes and acknowledge cycles make up the 36 clock cycles required for a single update to occur. A valid I²C address byte selects the AFE539F1-Q1.

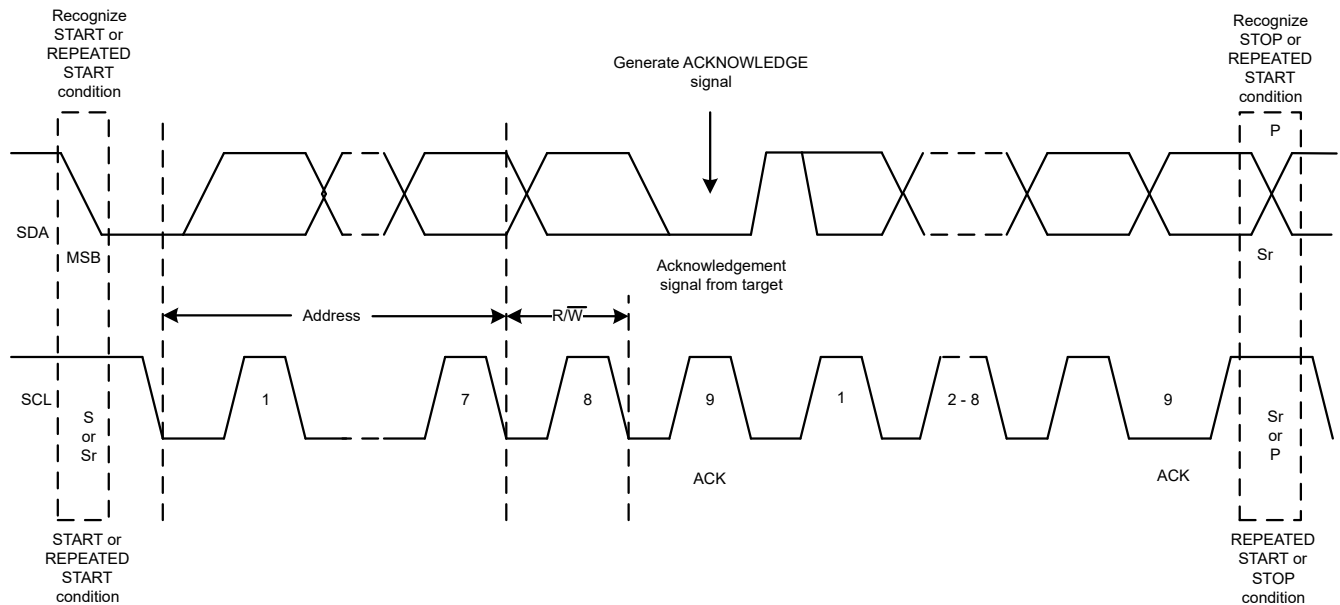


図 7-12. I²C Bus Protocol

The command byte sets the operating mode of the selected AFE539F1-Q1 device. For a data update to occur when the operating mode is selected by this byte, the AFE539F1-Q1 device must receive two data bytes: the most significant data byte (MSDB) and least significant data byte (LSDB). The AFE539F1-Q1 device performs an update on the falling edge of the acknowledge signal that follows the LSDB.

When using fast mode (clock = 400 kHz), the maximum update rate is limited to 10Ksps. Using fast mode plus (clock = 1 MHz), the maximum update rate is limited to 25Ksps. When a stop condition is received, the AFE539F1-Q1 device releases the I²C bus and awaits a new start condition.

7.5.2.2.1 Address Byte

The address byte, as shown in 表 7-7, is the first byte received from the controller device following the start condition. The first four bits (MSBs) of the address are factory preset to 1001. The next three bits of the address are controlled by the A0 pin. The A0 pin input can be connected to VDD, AGND, SCL, or SDA. The A0 pin is sampled during the first byte of each data frame to determine the address. The device latches the value of the address pin, and consequently responds to that particular address according to 表 7-8.

表 7-7. Address Byte

| COMMENT | MSB | | | | | | | LSB |
|-------------------|-----|-----|-----|-----|--------------------------------------|-----|-----|--------|
| | AD6 | AD5 | AD4 | AD3 | AD2 | AD1 | AD0 | |
| — | | | | | | | | R/W |
| General address | 1 | 0 | 0 | 1 | See 表 7-8 (target address column) | | | 0 or 1 |
| Broadcast address | 1 | 0 | 0 | 0 | 1 | 1 | 1 | 0 |

表 7-8. Address Format

| TARGET ADDRESS | A0 PIN |
|----------------|--------|
| 000 | AGND |
| 001 | VDD |
| 010 | SDA |
| 011 | SCL |

The AFE539F1-Q1 supports broadcast addressing, which is used for synchronously updating or powering down multiple AFE539F1-Q1 devices. When the broadcast address is used, the AFE539F1-Q1 responds regardless of the address pin state. Broadcast is supported only in write mode.

7.5.2.2.2 Command Byte

The *Register Names* table in the *Register Map* section lists the command byte in the ADDRESS column.

7.5.2.3 I²C Read Sequence

To read any register the following command sequence must be used:

1. Send a start or repeated start command with a target address and the $\overline{R/W}$ bit set to 0 for writing. The device acknowledges this event.
2. Send a command byte for the register to be read. The device acknowledges this event again.
3. Send a repeated start with the target address and the $\overline{R/W}$ bit set to 1 for reading. The device acknowledges this event.
4. The device writes the MSDB byte of the addressed register. The controller must acknowledge this byte.
5. Finally, the device writes out the LSDB of the register.

The broadcast address cannot be used for reading.

表 7-9. Read Sequence

| S | MSB | ... | R/W (0) | ACK | MSB | ... | LSB | ACK | Sr | MSB | ... | R/W (1) | ACK | MSB | ... | LSB | ACK | MSB | ... | LSB | ACK | | | |
|-----------------|---------------------------------|-----|------------|--------|---------------------------------|-----|-----|-----|--------|---------------------------------|-----|------------|-----|--------|-------------|-----|-----|------|------------|-------------|-----|--|--|------------|
| | ADDRESS BYTE セクション 7.5.2.2.1 | | | | COMMAND BYTE セクション 7.5.2.2.2 | | | | Sr | ADDRESS BYTE セクション 7.5.2.2.1 | | | | MSDB | | | | LSDB | | | | | | |
| From Controller | | | | Target | From Controller | | | | Target | From Controller | | | | Target | From Target | | | | Controller | From Target | | | | Controller |

7.6 Register Maps

表 7-10. Register Map

| REGISTER | MOST SIGNIFICANT DATA BYTE (MSDB) | | | | | | | | LEAST SIGNIFICANT DATA BYTE (LSDB) | | | | | | | |
|-----------------------|-----------------------------------|-------------------|----------|------------|---------|-------|----------|-----------|------------------------------------|------------|------|----------|---------|----------|------------|----------------|
| | BIT15 | BIT14 | BIT13 | BIT12 | BIT11 | BIT10 | BIT9 | BIT8 | BIT7 | BIT6 | BIT5 | BIT4 | BIT3 | BIT2 | BIT1 | BIT0 |
| NOP | NOP | | | | | | | | | | | | | | | |
| REF-GAIN-CONFIG | X | | | REF-GAIN | | | | RESERVED | | | | | | | | |
| COMMON-CONFIG | RESERVED | DEV-LOCK | RESERVED | EN-INT-REF | ADC-PDN | | RESERVED | | | | | | | | | |
| COMMON-TRIGGER | DEV-UNLOCK | | | | RESET | | | | RESERVED | | | | | | NVM-PROG | NVM-RELOAD |
| COMMON-PWM-TRIG | RESERVED | | | | | | | | | | | | | | | START-FUNCTION |
| GENERAL-STATUS | NVM-CRC-FAIL-INT | NVM-CRC-FAIL-USER | RESERVED | | | | | NVM-BUSY | DEVICE-ID | | | | | | VERSION-ID | |
| INTERFACE-CONFIG | X | | | TIMEOUT-EN | X | | | | | | | | FSDO-EN | X | SDO-EN | |
| STATE-MACHINE-CONFIG0 | RESERVED | | | | | | | | | | | | | SM-ABORT | SM-START | SM-EN |
| SRAM-CONFIG | X | | | | | | | SRAM-ADDR | | | | | | | | |
| SRAM-DATA | SRAM-DATA | | | | | | | | | | | | | | | |
| MAX-OUTPUT | RESERVED | | | | | | | | | MAX-OUTPUT | | | | | | |
| MIN-OUTPUT | RESERVED | | | | | | | | | MIN-OUTPUT | | | | | | |
| FUNCTION-COEFFICIENT | FUNCTION-COEFFICIENT | | | | | | | | | | | | | | | |
| PWM-FREQUENCY | RESERVED | | | | | | | | | | | PWM-FREQ | | | | |

Note: Shaded cells indicate the register bits or fields that are stored in NVM.

Note: X = Don't care.

表 7-11. Register Names

| I ² C/SPI ADDRESS (COMMAND BYTE) | SRAM ADDRESS | REGISTER NAME | SECTION |
|--|-----------------|-----------------------|------------------------------|
| 00h | — | NOP | セクション 7.6.1 |
| 15h | — | REF-GAIN-CONFIG | セクション 7.6.2 |
| 1Fh | — | COMMON-CONFIG | セクション 7.6.3 |
| 20h | — | COMMON-TRIGGER | セクション 7.6.4 |
| 21h | — | COMMON-PWM-TRIG | セクション 7.6.5 |
| 22h | — | GENERAL-STATUS | セクション 7.6.6 |
| 26h | — | INTERFACE-CONFIG | セクション 7.6.7 |
| 27h | — | STATE-MACHINE-CONFIG0 | セクション 7.6.8 |
| 2Bh | — | SRAM-CONFIG | セクション 7.6.9 |
| 2Ch | — | SRAM-DATA | セクション 7.6.10 |
| — | 20h | MAX-OUTPUT | セクション 7.6.11 |
| — | 21h | MIN-OUTPUT | セクション 7.6.12 |
| — | 22h | FUNCTION-COEFFICIENT | セクション 7.6.13 |
| — | 23h | PWM-FREQUENCY | セクション 7.6.14 |

7.6.1 NOP Register (address = 00h) [reset = 0000h]

図 7-13. NOP Register

| | | | | | | | | | | | | | | | |
|--------|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| NOP | | | | | | | | | | | | | | | |
| R/W-0h | | | | | | | | | | | | | | | |

表 7-12. NOP Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|------|-------|------|-------|--------------|
| 15-0 | NOP | R/W | 0000h | No operation |

7.6.2 REF-GAIN-CONFIG Register (address = 15h) [reset = 0401h]

図 7-14. REF-GAIN-CONFIG Register

| | | | | | | | | | | | | | | | |
|------|----|----------|----|----|----|----------|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| X | | REF-GAIN | | | | RESERVED | | | | | | | | | |
| X-0h | | R/W-001 | | | | R/W-001h | | | | | | | | | |

表 7-13. REF-GAIN-CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|-------|----------|------|-------|--|
| 15-13 | X | X | 0h | Don't care. |
| 12-10 | REF-GAIN | R/W | 001 | 000: Gain = 1 ×, external reference on VREF/MODE pin. 001: Gain = 1 ×, VDD as reference (default). 010: Gain = 1.5 ×, internal reference. 011: Gain = 2 ×, internal reference. 100: Gain = 3 ×, internal reference. 101: Gain = 4 ×, internal reference. Others: NA. |
| 9-0 | RESERVED | R/W | 001h | Always write 001h. |

7.6.3 COMMON-CONFIG Register (address = 1Fh) [reset = 13FFh]

図 7-15. COMMON-CONFIG Register

| | | | | | | | | | | | | | | | |
|----------|----------|----------|------------|---------|----|----------|---|---|---|---|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| RESERVED | DEV-LOCK | RESERVED | EN-INT-REF | ADC-PDN | | RESERVED | | | | | | | | | |
| R/W-0h | R/W-0h | R/W-0h | R/W-1 | R/W-0h | | R/W-3FFh | | | | | | | | | |

表 7-14. COMMON-CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|------|------------|------|-------|---|
| 15 | RESERVED | R/W | 0 | Always write 0. |
| 14 | DEV-LOCK | R/W | 0 | 0: Device not locked 1: Device locked, the device locks all the registers. To set this bit back to 0 (unlock device), write to the unlock code to the DEV-UNLOCK field in the COMMON-TRIGGER register first, followed by a write to the DEV-LOCK bit as 0. |
| 13 | RESERVED | R/W | 0 | Always write 0. |
| 12 | EN-INT-REF | R/W | 1 | 0: Disable internal reference 1: Enable internal reference. This bit must be set before using internal reference gain settings. |
| 11 | ADC-PDN | R/W | 0 | 00: Power-up ADC. 01: Power-down ADC with 10 KΩ to AGND. 10: Power-down ADC with 100 KΩ to AGND. 11: Power-down ADC with Hi-Z to AGND. |
| 10-0 | RESERVED | R/W | 3FFh | Always write 3FFh. |

7.6.4 COMMON-TRIGGER Register (address = 20h) [reset = 0000h]

图 7-16. COMMON-TRIGGER Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|------------|----|----|----|--------|----|---|---|----------|---|---|---|---|---|----------|------------|
| DEV-UNLOCK | | | | RESET | | | | RESERVED | | | | | | NVM-PROG | NVM-RELOAD |
| R/W-0h | | | | R/W-0h | | | | R/W-00h | | | | | | R/W-0h | R/W-0h |

表 7-15. COMMON-TRIGGER Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|-------|------------|------|-------|--|
| 15-12 | DEV-UNLOCK | R/W | 0h | 0101: Device unlocking password. Others: Don't care. |
| 11-8 | RESET | W | 0h | 1010: POR reset triggered. This field is self-resetting. Others: Don't care. |
| 7-2 | RESERVED | R/W | 00h | Always write 0. |
| 1 | NVM-PROG | R/W | 0 | 0: NVM write not triggered. 1: NVM write triggered. This bit is self-resetting. |
| 0 | NVM-RELOAD | R/W | 0 | 0: NVM reload not triggered. 1: Reload data from NVM to register map. This bit is self-resetting. |

7.6.5 COMMON-PWM-TRIG Register (address = 21h) [reset = 0001h]

图 7-17. COMMON-PWM-TRIG Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----------|----|----|----|----|----|---|---|---|---|---|---|---|---|----------------|---|
| RESERVED | | | | | | | | | | | | | | START-FUNCTION | |
| R/W-0000h | | | | | | | | | | | | | | R/W-0h | |

表 7-16. COMMON-PWM-TRIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|------|----------------|------|-------|--|
| 15-1 | RESERVED | R/W | 0000h | Always write 0000h. |
| 0 | START-FUNCTION | R/W | 0 | 0: Stop PWM generation. 1: Invalid. This bit is automatically set by the state machine. |

7.6.6 GENERAL-STATUS Register (address = 22h) [reset = 00h, DEVICE-ID, VERSION-ID]

☒ 7-18. GENERAL-STATUS Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|------------------|-------------------|-------|----|----|----|---|---|----------|-----------|---|---|---|---|---|------------|
| NVM-CRC-FAIL-INT | NVM-CRC-FAIL-USER | X | | | | | | NVM-BUSY | DEVICE-ID | | | | | | VERSION-ID |
| R-0h | R-0h | X-00h | | | | | | R-0h | R-0h | | | | | | R-0h |

表 7-17. GENERAL-STATUS Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|-----|-------------------|------|-------|---|
| 15 | NVM-CRC-FAIL-INT | R | 0 | 0: No CRC error in OTP. 1: Indicates a failure in OTP loading. A software reset or power-cycle can bring the device out of this condition in case of temporary failure. |
| 14 | NVM-CRC-FAIL-USER | R | 0 | 0: No CRC error in NVM loading. 1: Indicates a failure in NVM loading. The register settings are corrupted. The device allows all operations during this error condition. Reprogram the NVM to get original state. A software reset brings the device out of this error condition. |
| 13 | X | X | 00h | Don't care. |
| 8 | NVM-BUSY | R | 0 | 0: NVM is available for read and write. 1: NVM is not available for read or write. |
| 7-2 | DEVICE-ID | R | 19h | Device identifier. |
| 1-0 | VERSION-ID | R | 0 | Version identifier. |

7.6.7 INTERFACE-CONFIG Register (address = 26h) [reset = 0000h]

☒ 7-19. INTERFACE-CONFIG Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|------|----|------------|------|----|----|---|---|---|---|---|---|---|---------|------|--------|
| X | | TIMEOUT-EN | X | | | | | | | | | | FSDO-EN | X | SDO-EN |
| X-0h | | R/W-0h | X-0h | | | | | | | | | | R/W-0h | X-0h | R/W-0h |

表 7-18. INTERFACE-CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|---------|------------|------|-------|---|
| 15 - 13 | X | X | 0h | Don't care. |
| 12 | TIMEOUT-EN | R/W | 0 | 0: I ² C timeout disabled. 1: I ² C timeout enabled. |
| 11 - 3 | X | X | 0h | Don't care. |
| 2 | FSDO-EN | R/W | 0 | 0: Fast SDO disabled. 1: Fast SDO enabled. |
| 1 | X | X | 0 | Don't care. |
| 0 | SDO-EN | R/W | 0 | 0: SDO disabled. 1: SDO enabled. |

7.6.8 STATE-MACHINE-CONFIG0 Register (address = 27h) [reset = 0003h]

图 7-20. STATE-MACHINE-CONFIG0 Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------|----|----|----|----|----|---|---|---|---|---|---|---|----------|----------|--------|
| RESERVED | | | | | | | | | | | | | SM-ABORT | SM-START | SM-EN |
| R/W-0h | | | | | | | | | | | | | R/W-0h | R/W-0h | R/W-0h |

表 7-19. STATE-MACHINE-CONFIG0 Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|--------|----------|------|-------|---|
| 15 - 3 | RESERVED | R/W | 0000h | Always write 0. |
| 2 | SM-ABORT | R/W | 0 | 0: State machine not aborted. 1: State machine aborted. |
| 1 | SM-START | R/W | 0 | 0: State machine stopped. 1: State machine started. The state machine must be enabled using the SM-EN bit. |
| 0 | SM-EN | R/W | 0 | 0: State machine disabled. 1: State machine enabled. |

7.6.9 SRAM-CONFIG Register (address = 2Bh) [reset = 0000h]

图 7-21. SRAM-CONFIG Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------|----|----|----|----|----|---|---|-----------|---|---|---|---|---|---|---|
| X | | | | | | | | SRAM-ADDR | | | | | | | |
| X-00h | | | | | | | | R/W-00h | | | | | | | |

表 7-20. SRAM-CONFIG Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|------|-----------|------|-------|--|
| 15-8 | X | X | 00h | Don't care |
| 7-0 | SRAM-ADDR | R/W | 00h | 8-bit SRAM address. Writing to this register field configures the SRAM address to be accessed next. This address automatically increments after a write to the SRAM. |

7.6.10 SRAM-DATA Register (address = 2Ch) [reset = 0000h]

图 7-22. SRAM-DATA Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----------|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| SRAM-DATA | | | | | | | | | | | | | | | |
| R/W-0000h | | | | | | | | | | | | | | | |

表 7-21. SRAM-DATA Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|------|-----------|------|-------|--|
| 15-0 | SRAM-DATA | R/W | 0000h | 16-bit SRAM data. Data are written to or read from the address configured in the SRAM-CONFIG register. |

7.6.11 MAX-OUTPUT Register (SRAM address = 20h) [reset = 007Fh]

注

This register address is mapped to SRAM. Use the SRAM-CONFIG and SRAM-DATA registers to read and write.

図 7-23. MAX-OUTPUT Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----------|----|----|----|----|----|---|---|------------|---|---|---|---|---|---|---|
| RESERVED | | | | | | | | MAX-OUTPUT | | | | | | | |
| R/W-0000h | | | | | | | | R/W-7Fh | | | | | | | |

表 7-22. MAX-OUTPUT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|------|------------|------|-------|-------------------------------------|
| 15-7 | RESERVED | R/W | 0000h | Always write 0000h. |
| 6-0 | MAX-OUTPUT | R/W | 7Fh | 7-bit maximum limit for PWM output. |

7.6.12 MIN-OUTPUT Register (SRAM address = 21h) [reset = 0000h]

注

This register address is mapped to SRAM. Use the SRAM-CONFIG and SRAM-DATA registers to read and write.

図 7-24. MIN-OUTPUT Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----------|----|----|----|----|----|---|---|------------|---|---|---|---|---|---|---|
| RESERVED | | | | | | | | MIN-OUTPUT | | | | | | | |
| R/W-0000h | | | | | | | | R/W-00h | | | | | | | |

表 7-23. MIN-OUTPUT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|------|------------|------|-------|-------------------------------------|
| 15-7 | RESERVED | R/W | 0000h | Always write 0000h. |
| 6-0 | MIN-OUTPUT | R/W | 00h | 7-bit minimum limit for PWM output. |

7.6.13 FUNCTION-COEFFICIENT Register (SRAM address = 22h) [reset = 01F4h]

注

This register address is mapped to SRAM. Use the SRAM-CONFIG and SRAM-DATA registers to read and write.

図 7-25. FUNCTION-COEFFICIENT Register

| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------------------|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|
| FUNCTION-COEFFICIENT | | | | | | | | | | | | | | | |
| R/W-01F4h | | | | | | | | | | | | | | | |

表 7-24. FUNCTION-COEFFICIENT Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|------|----------------------|------|-------|--|
| 15-0 | FUNCTION-COEFFICIENT | R/W | 01F4h | 16-bit function coefficient (K) as specified in 式 2 and 式 3. |

7.6.14 PWM-FREQUENCY Register (SRAM address = 23h) [reset = 000Bh]

注

This register address is mapped to SRAM. Use the SRAM-CONFIG and SRAM-DATA registers to read and write.

図 7-26. PWM-FREQUENCY Register

| | | | | | | | | | | | | | | | |
|----------|----|----|----|----|----|---|---|---|---|----------|---|---|---|---|---|
| 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| RESERVED | | | | | | | | | | PWM-FREQ | | | | | |
| R/W-000h | | | | | | | | | | R/W-0Bh | | | | | |

表 7-25. PWM-FREQUENCY Register Field Descriptions

| Bit | Field | Type | Reset | Description |
|------|-----------|------|-------|--|
| 15-5 | RESERVED | R/W | 000h | Always write 000h. |
| 15-0 | SRAM-DATA | R/W | 0Bh | 5-bit PWM frequency setting as specified in 表 7-2. |

8 Application and Implementation

注

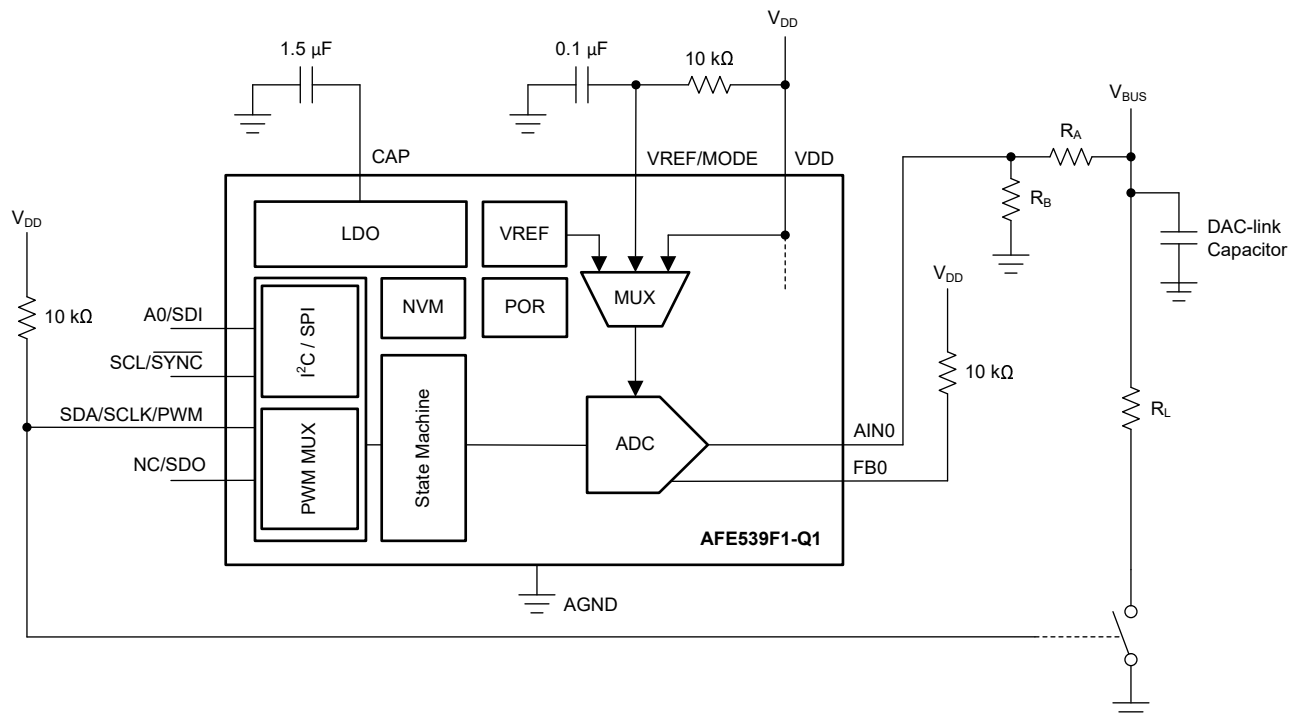
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The AFE539F1-Q1 is a smart analog front end (AFE) that includes an ADC channel, PWM output, NVM, internal reference, and are available in a tiny 3-mm × 3-mm package. The AFE539F1-Q1 have an integrated state machine that is pre-programmed as a constant power output controller. The ADC has a full-scale of $V_{DD}/3$. Use an external attenuator when the input exceeds this range. The PWM provides a 7-bit duty-cycle output on the SDA/SCLK/PWM pin. Pull the VREF/MODE pin high to enable the PWM output. Pulling the VREF/MODE pin low enables the I²C or SPI programming mode. The application parameters are programmed in the device using I²C or SPI and stored in the NVM.

8.2 Typical Application

This design uses the AFE539F1-Q1 to maintain constant power dissipation on a restive load, independent of the applied voltage. Modulating the power resistor via a switch can change the effective resistance and maintain constant power as the supply voltage (V_{BUS}) changes. The AFE539F1-Q1 has an integrated state machine that converts the ADC input to a PWM output based on the transfer function in 式 2. Parameters such as the PWM frequency, maximum and minimum duty cycle outputs, and the K term in 式 2 are user programmable and can be saved in the NVM. The control loop runs standalone without the need for a processor after initial programming. Use this circuit in constant power heating, or automotive DC-link capacitor discharge applications. 図 8-1 shows an example schematic for this application.



Constant Power Discharge Circuit

8.2.1 Design Requirements

表 8-1. Design Parameters

| PARAMETER | VALUE |
|-----------------------------------|-----------|
| PWM Frequency | 3.052 kHz |
| Bus voltage (V _{BUS}) | 48 V |
| Load resistance (R _L) | 5 Ω |
| Power dissipation limit | 50 W |
| Maximum duty cycle | 100% |
| Minimum duty cycle | 0% |

8.2.2 Detailed Design Procedure

Use VDD (5 V) as reference with gain 1 × to achieve an input range of (VDD/3) = 1.67 V, using 表 7-1. With a bus voltage of 48 V and ADC input range of 1.67 V, the external attenuation required is 28.74. Therefore, the attenuation resistors can be chosen as R_A = 100 kΩ and R_B = 3.6 kΩ. To limit the power dissipation to 50 W, the effective load resistance (R_{L-eff}) is calculated as (V_{BUS}²/P) = 46.08 Ω. That means a minimum duty-cycle of (R_L/R_{L-eff}) = 10.85% is required. In a 7-bit scale, 10.85% corresponds to 13.89d. The required function coefficient, K can be calculated using 式 4 to be 443.6d (0x01BC).

$$K = \frac{D_{\text{MIN}} \times (\text{ADC} - \text{DATA}_{\text{MAX}})^2}{2^{15}} \quad (4)$$

The PWM output pin is an open drain output. The PWM output pin must be pulled up to the desired IO voltage using an external resistor. The PWM frequency is set in the PWM-FREQUENCY SRAM location (SRAM: 0x23). 表 7-2 defines the codes for each available frequency. This example uses a PWM frequency of 3.052 kHz. Set the maximum and minimum PWM duty cycles limits in the MAX-OUTPUT and MIN-OUTPUT SRAM locations. The PWM duty cycle output is configured by a 7-bit code. The maximum code is 127d. 127d sets the PWM duty cycle to 100%. 表 7-3 provides more details about PWM duty cycle computation in AFE539F1-Q1.

Follow these guidelines to setup the registers on AFE539F1-Q1:

- Set the VREF/MODE pin low to enable the digital pins for programming mode.
- Stop the state machine before updating the application parameters by writing 0 to the STATE-MACHINE-CONFIG0 register.
- If the PWM generator is already running, stop the PWM generator before any changes to the PWM frequency take effect. Write a 0 to the START-FUNCTION field in the COMMON-PWM-TRIG register (0x21) to stop the PWM generator. The PWM generator automatically starts when the state machine is enabled.
- Set all of the application parameters shown in 表 8-2. Use these locations to save the settings in NVM.
- Configure the reference for the ADC in the REF-GAIN-CONFIG register.
- Power on the ADC channel using the COMMON-CONFIG register.
- Start the state machine by writing 0x3 to the STATE-MACHINE-CONFIG0.
- Trigger an NVM write by setting the NVM-PROG bit in the COMMON-TRIGGER register (0x20) to 1.
- Set the VREF/MODE pin high to enable the digital pins for standalone mode. This is required to see the PWM output on the digital pin.

表 8-2. Application Parameters

| REGISTER FIELD NAME | ADDRESS[FIELD] | ADDRESS LOCATION |
|-----------------------|------------------|------------------|
| MAX-OUTPUT | 0x20[6:0] | SRAM |
| MIN-OUTPUT | 0x21[6:0] | SRAM |
| FUNCTION-COEFFICIENT | 0x22[15:0] | SRAM |
| PWM-FREQUENCY | 0x23[4:0] | SRAM |
| REF-GAIN-CONFIG | 0x15[12:10][4:0] | Register |
| COMMON-CONFIG | 0x1F[15:0] | Register |
| STATE-MACHINE-CONFIG0 | 0x27[2:0] | Register |

The pseudocode for this application example is as follows:

```
//SYNTAX: WRITE <REGISTER NAME(Hex Code)>, <MSB DATA>, <LSB DATA>
//Stop the state machine
WRITE STATE-MACHINE-CONFIG0(0x27), 0x00, 0x01
//Stop the PWM generator
WRITE COMMON-PWM-TRIG(0x21), 0x00, 0x00
//Set the PWM frequency to 3.052 kHz
WRITE PWM-FREQUENCY(SRAM 0x23), 0x00, 0x07
//Set the maximim and minimum PWM duty cycles
WRITE MAX-OUTPUT(SRAM 0x20), 0x00, 0x7F
WRITE MIN-OUTPUT(SRAM 0x21), 0x00, 0x00
//Set the function coefficient (K)
WRITE FUNCTION-COEFFICIENT(SRAM 0x22), 0x01, 0xBC
//Set the ADC reference to VDD (this is the device default)
WRITE REF-GAIN-CONFIG(0x15), 0x04, 0x01
//Power on ADC
WRITE COMMON-CONFIG(0x1F), 0x03, 0xFF
//Start the state machine
WRITE STATE-MACHINE-CONFIG0(0x27), 0x00, 0x03
//Save settings to NVM
WRITE COMMON-TRIGGER(0x20), 0x00, 0x02
//Pull the VREF/MODE pin high to enter standalone mode
```

8.2.3 Application Curve

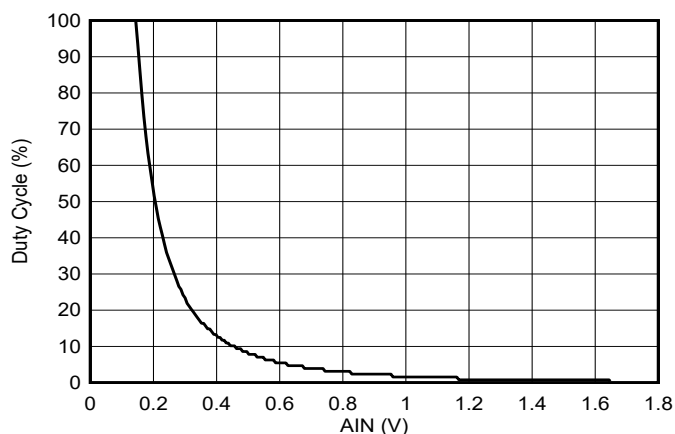


图 8-1. PWM Duty Cycle vs Input Voltage

8.3 Power Supply Recommendations

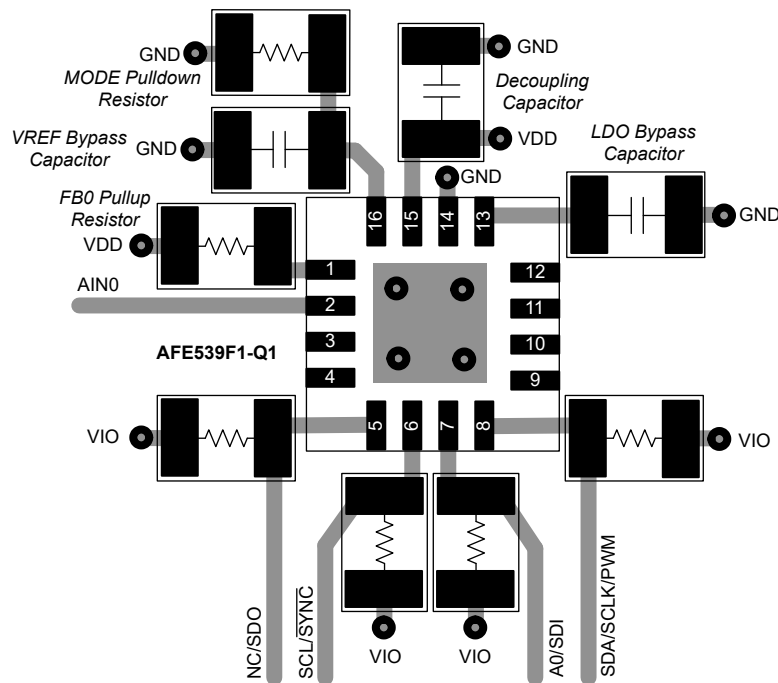
The AFE539F1-Q1 do not require specific power-supply sequencing. These devices require a single power supply, V_{DD} . However, make sure the external voltage reference is applied after V_{DD} powers on. Use a 0.1- μ F decoupling capacitor for the V_{DD} pin. Use a bypass capacitor with a value approximately 1.5 μ F for the CAP pin.

8.4 Layout

8.4.1 Layout Guidelines

The AFE539F1-Q1 pin configuration separates the analog, digital, and power pins for an optimized layout. For signal integrity, separate the digital and analog traces, and place decoupling capacitors close to the device pins.

8.4.2 Layout Example



8-2. Layout Example

Note: The ground and power planes have been omitted for clarity. Connect the thermal pad to ground.

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

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9.5 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|--------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| AFE539F1RTERQ1 | Active | Production | WQFN (RTE) 16 | 3000 LARGE T&R | Yes | FULL NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | A59F1Q |
| AFE539F1RTERQ1.A | Active | Production | WQFN (RTE) 16 | 3000 LARGE T&R | Yes | FULL NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | A59F1Q |

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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GENERIC PACKAGE VIEW

RTE 16

WQFN - 0.8 mm max height

3 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4225944/A



4219117/B 04/2022

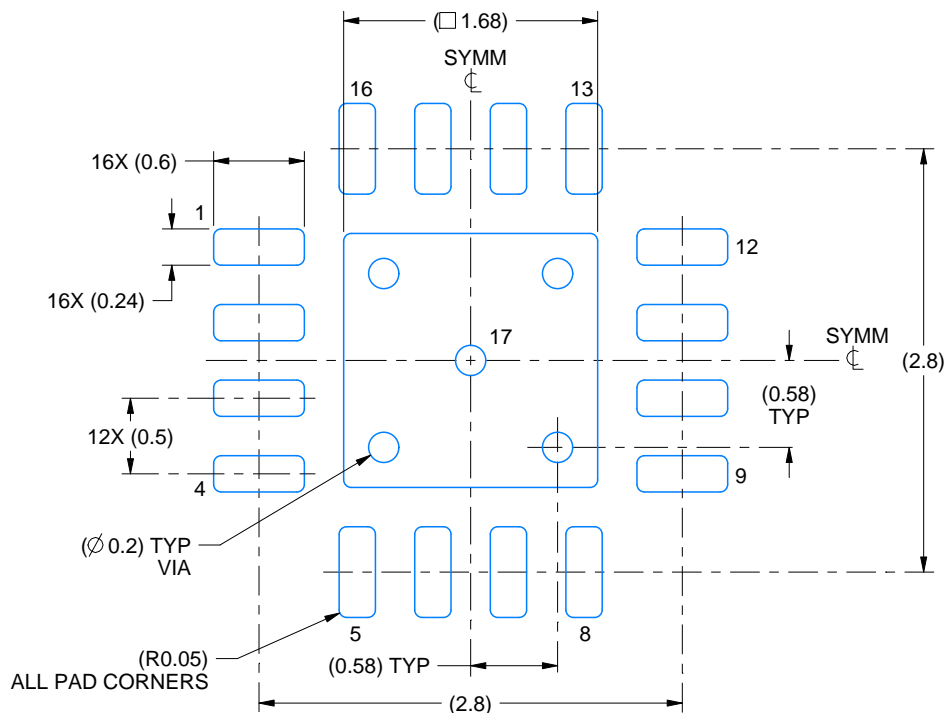
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

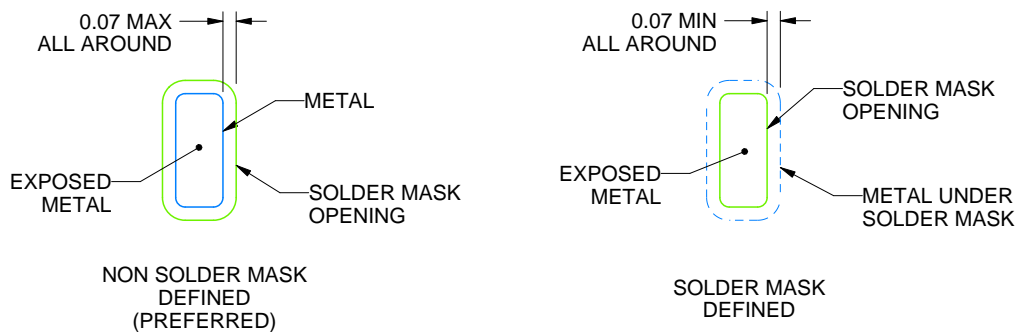
RTE0016C

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X



SOLDER MASK DETAILS

4219117/B 04/2022

NOTES: (continued)

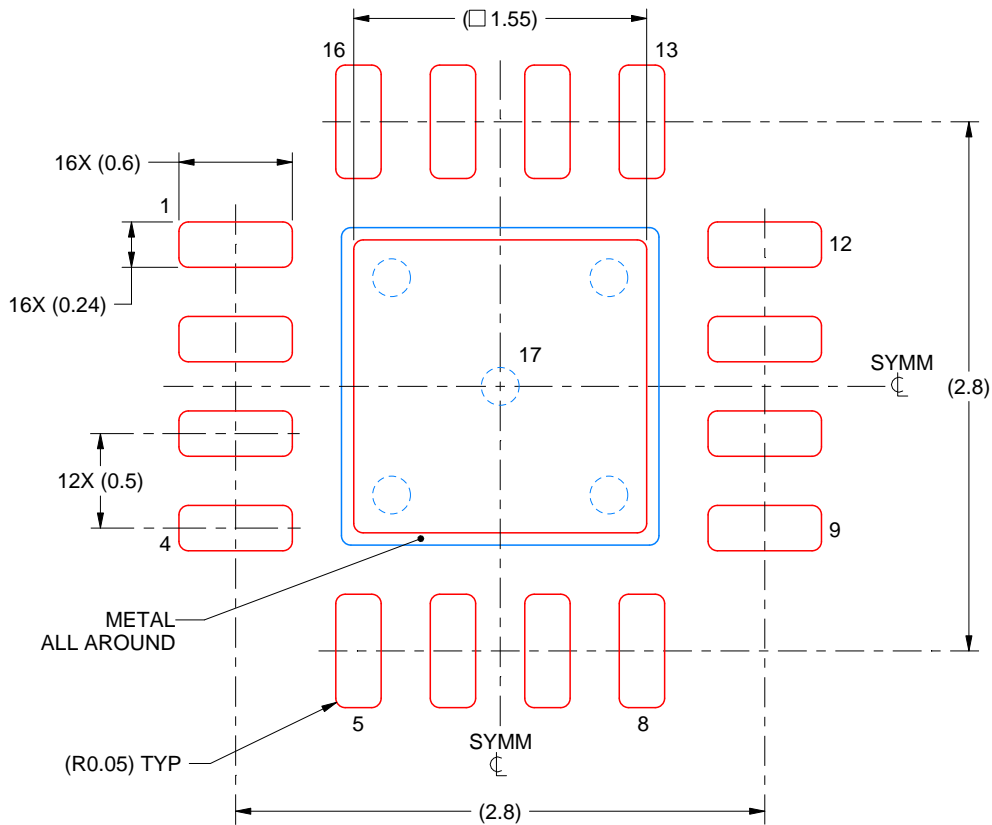
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RTE0016C

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 17:
85% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

4219117/B 04/2022

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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